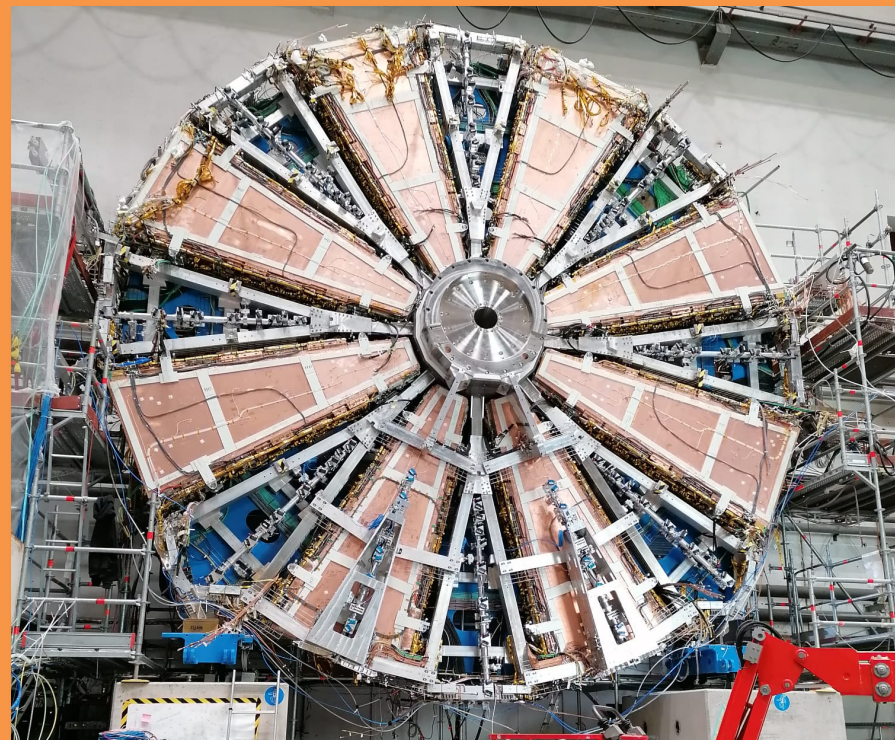


Update on production and stability of the ATLAS/NSW MicroMegas chambers

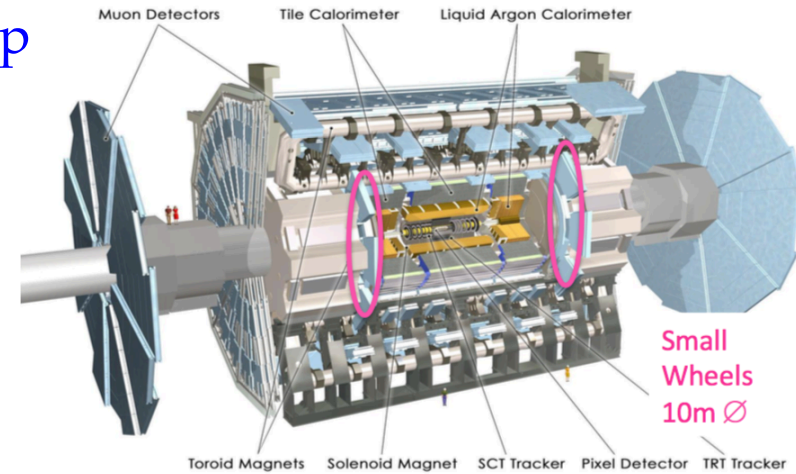


Giada Mancini - LNF INFN
on behalf of the ATLAS NSW MicroMegas group

- Micromegas for the ATLAS NSW Phase I Upgrade
- HV stability issue, resistivity issue, passivation solution
- Test with different gas mixtures (mainly ternary mixture adding 2% Isobuthane)
- Pure Argon test to recover a resistive behaving section
- Status of the Upgrade

The **NSW** will replace the **innermost end-cap station** of the Muon Spectrometer

- **Main ATLAS upgrade during the LS2 (Phase-I)**
- Designed to operate also at HL-LHC luminosity $\gtrsim 5 \times 10^{34} \text{ cm}^{-2}\text{s}^{-1}$ (Phase-II)
- **Angular coverage: $1.3 < |\eta| < 2.7$**

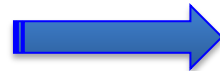


Located at $z = \pm 7\text{m}$ from IP the first MS station in the forward region (End-Cap)

- **Goals:**
 - p_T resolution: $\sim 15\%$ at 1 TeV \rightarrow ~ 100 mm per plane on a multilayer station
 - **able to cope with high fluxes and reject fake muon triggers**
- Improvements in technologies needed both for precision tracking and trigger

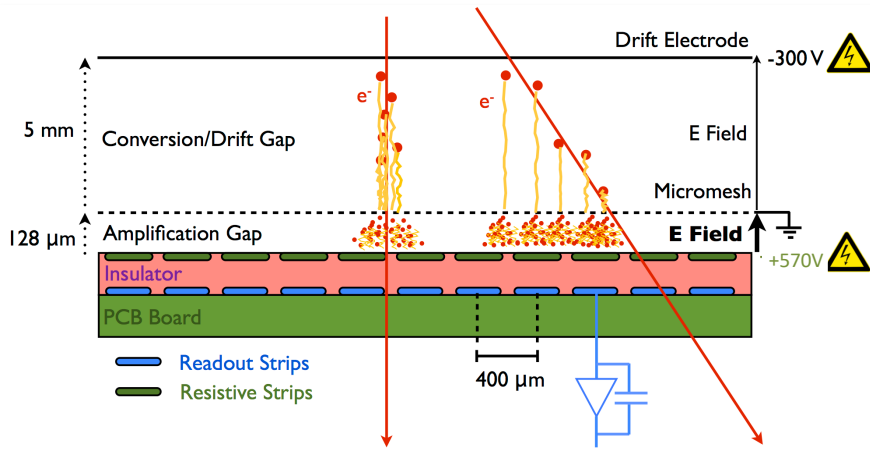
Present SW

- **CSC** and **MDT** for precision coord.
- **TGC** for the 2nd coord.
 - **trigger up to $|\eta| < 2.0$**



NSW

- **Micromegas** primary precision tracking
- **sTGC** primary for trigger

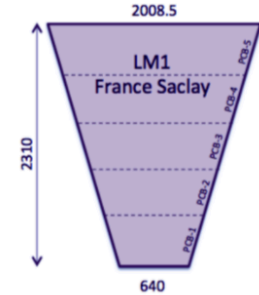
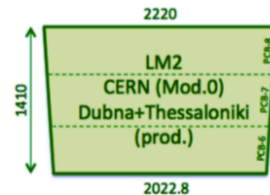
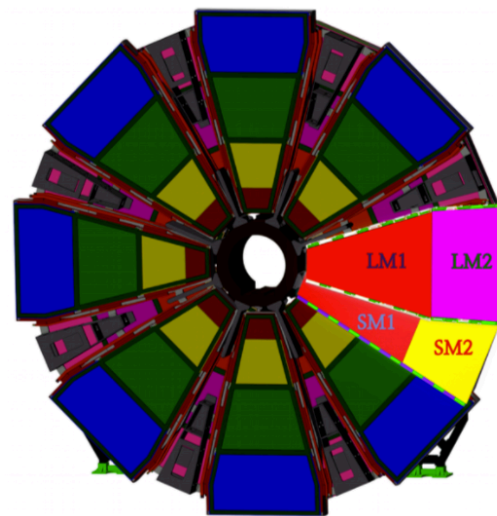
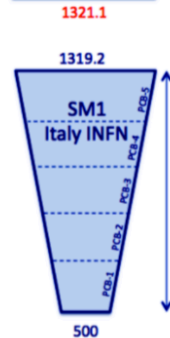
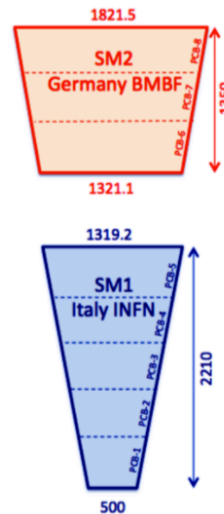


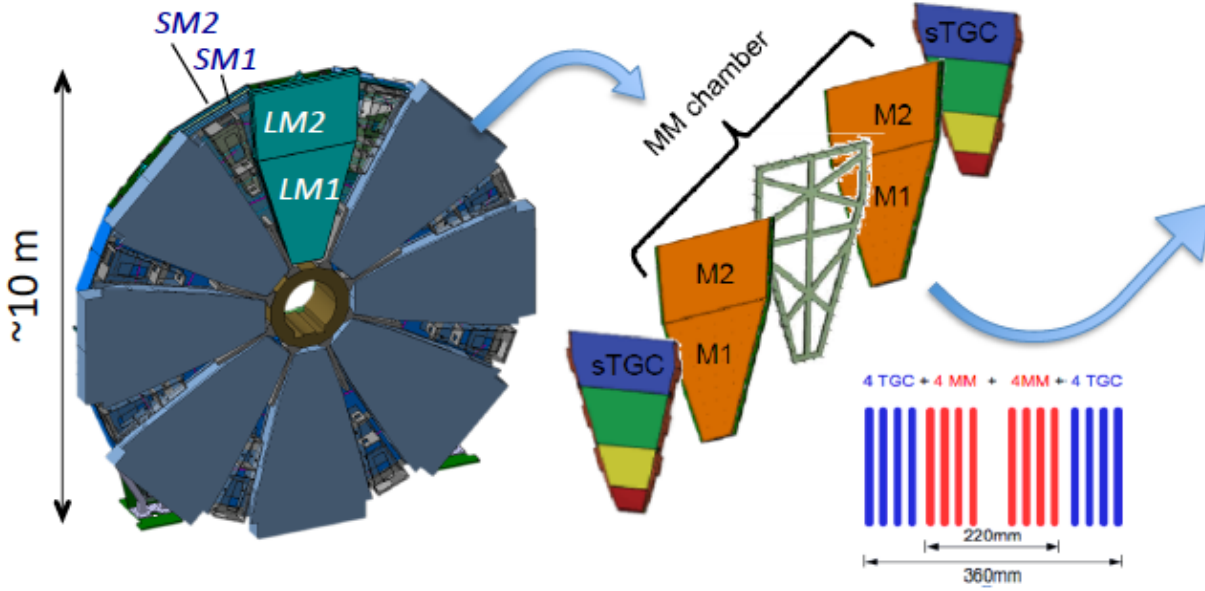
Working conditions:

- gas: 93% Ar - 7% CO₂ (further studies ongoing)
- conversion gap 5 mm, amplification gap 128 μm
- HV (metallic mesh grounded):
 - Conversion: HV_{drift} = -300 V, h=5mm, E_C ~ 600 V/cm
 - Amplification: HV_{RO} = 570 V, h=128μm, E_A ~ 50 kV/cm
- resistivity strip ≈ 10 MΩ/cm (to reduce the probability of discharges) are overlaid to copper signal strips
- Copper signal strips: width 300 μm, strip pitch 425-450 μm
- Mesh integrated in the drift panel structure

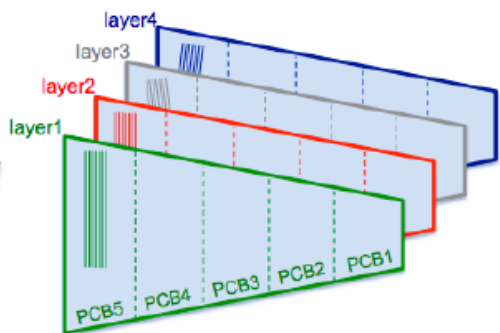
NSW, wheel structure:

- 8 large sectors (LM) and 8 small ones (SM) (2 MM modules per sector)
- MM aim: **precision tracking** (between 2 sTGC chambers for trigger)
- 4 type of chambers: LM 1-2, SM 1-2
- production shared between several institutes: Italy (SM1), Germany (SM2), France (LM1), Russia / Greece (LM2 – CERN for drawings and first prototypes)





MM quadruplet



Each MM module has 4 detection planes

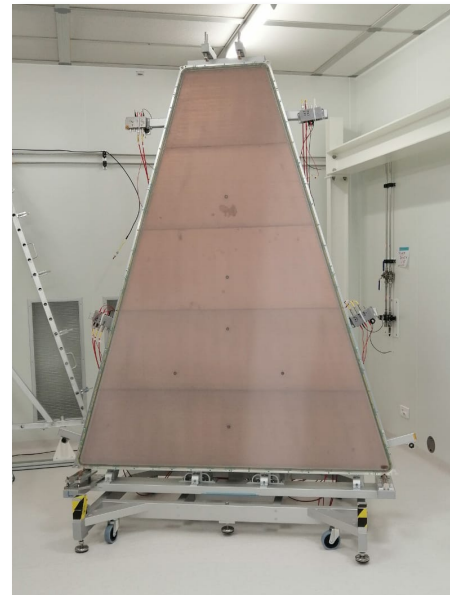
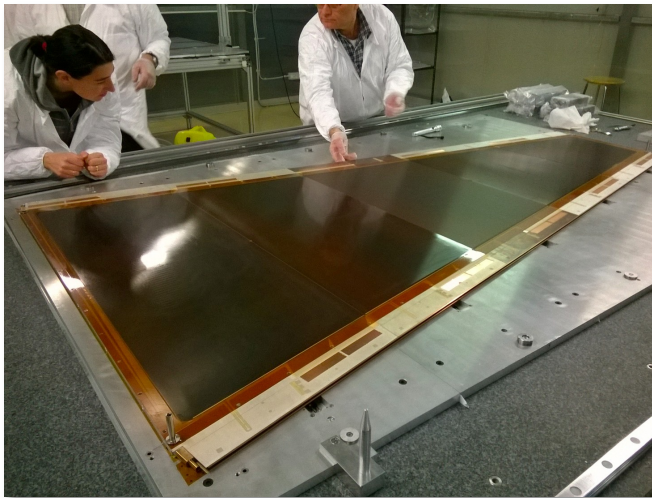
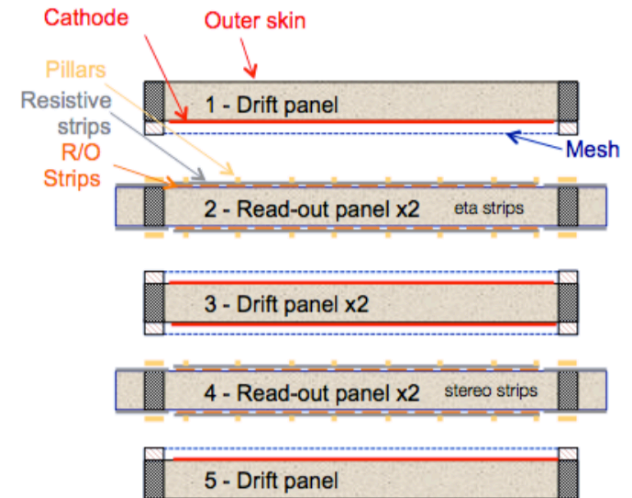
Each NSW has 16 sectors:
8 Large + 8 Small

Each Sector is a sandwich of
sTGC and MM quadruplets

- >8000 ch. per layer -> >32000 ch. per quadruplet -> ~1M ch. per Wheel
- 8x2 = 16 independent HV sectors per DW layer

MM quadruplet:

- Cathode (Drift) and Anode (ReadOut) planes built on sides of 5 panels stiffened trough the use of honeycomb structures
- 2 read out panels (1 eta and 1 stereo with strips inclined by $\pm 1.5^\circ$ in order to reconstruct the 2nd coordinate) -> RO pcbs are based on boards done in industries
- 3 drift panels (cathode pcbs + glued meshes)



The resistive MicroMegas chambers are frontier Micro-Pattern Gas Detector which are designed and built for the first time on large dimensions $O(m^2)$.

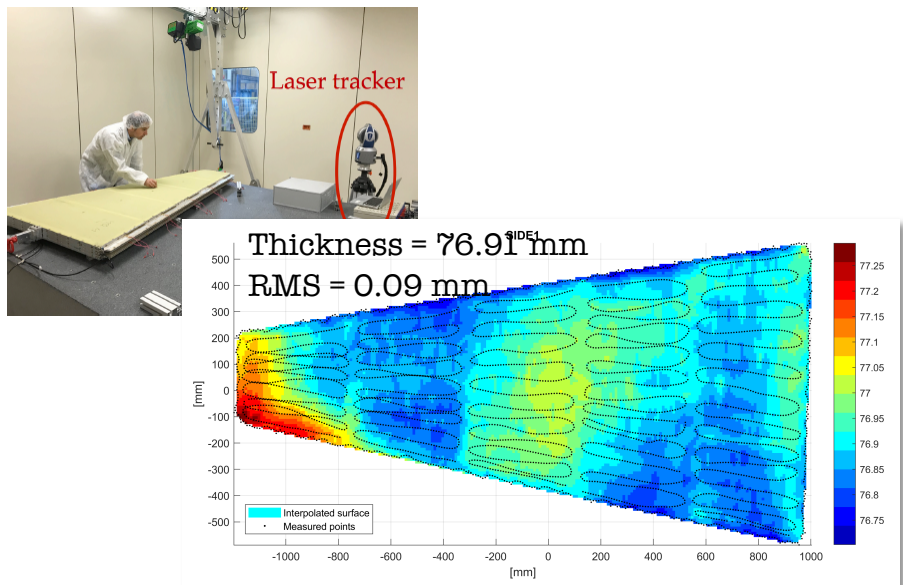
MicroMegas construction challenges:

- Very high mechanical precision in order to get **$\sim 15\%$ p_T resolution at 1 TeV**
 - strip alignment on each layer of **$40 \mu m$ of precision in η**
 - **planarity within $100 \mu m$ RMS**
 - **both request challenging because of the large detector dimensions**
- **technological transfer of Read-out PCBs production** with extremely high quality (pillars shape, resistivity homogeneity, quality of the PCB edges)
- **stability against discharges** with an high electric field (~ 50 kV / cm) on a surface of $O(m^2)$

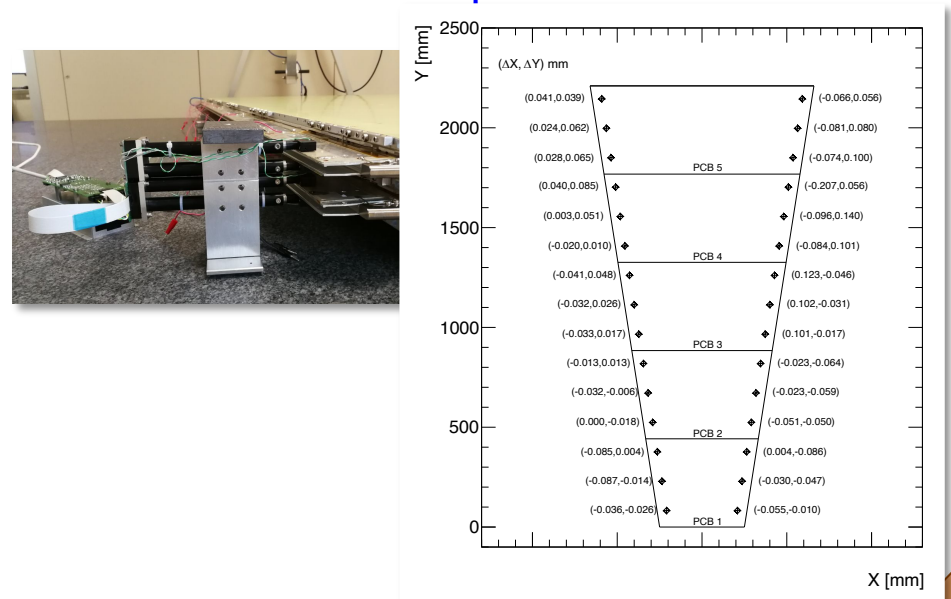
MM modules Assembly

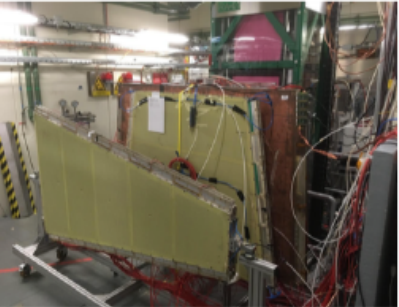
- Production concept is the same for all four module types
- Slightly different technical solutions adopted at the various construction sites for both construction of single panels and module assembly
- The assembling of a module (few days) must be performed very carefully
 - After each gas gap is closed, test for HV stability are performed before working on the panel for the next gap
 - After all gaps are closed a test for gas leaks is also performed
- Careful QA/QC program implemented to check all parts and production steps

Planarity of the module measured with a laser tracker (specific: RMS < 100mm)

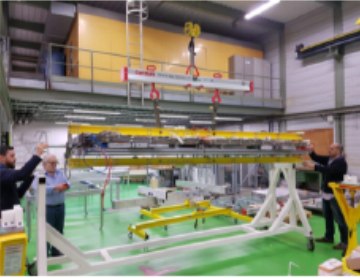


Relative layers alignment measured with the RASNIK technique




Gas tightness: 4 MM can be tested in parallel
HV: 3 MM tested in parallel
GIF++: 2 MM in parallel



All **lifting/rotating tools** for SM1/SM2/LM1/LM2 available for the Small and Large Wedge mounting



LV/HV/optical fibers/ data cables (TwinAx)/ Temperature probes
 --> 54 km of TwinAx cable being covered with Kapton!



Testing the complete elex setup:
MMFE8/L1DDC/ADDC (FE/data concentrator/trigger) +optical Felix system

- DW final validation at CRS
- Remapping HV
- Electronic installation
- Data taking and efficiency maps

Chambers tested at the Gamma Ray Irradiation Facility

(GIF++), North Area of SPS at CERN

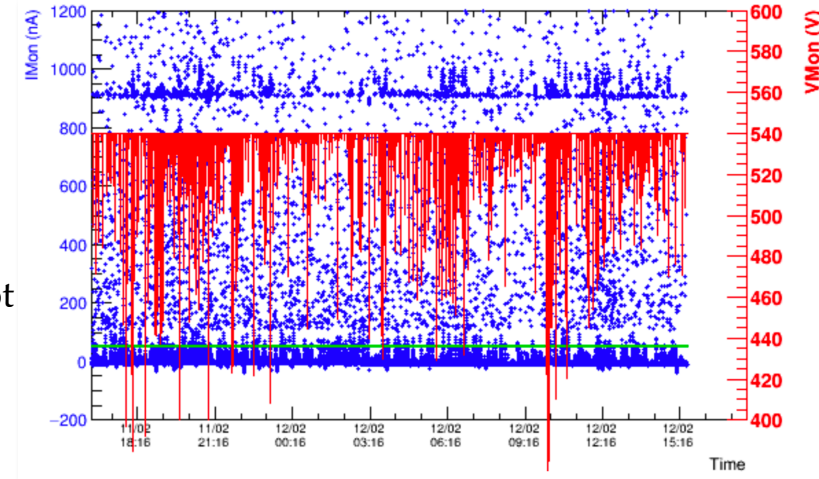
- The facility uses a ^{137}Cs source of di $\sim 13 \text{ TBq}$ (662 keV)
- Filters used to adjust the flux intensity
- Now up to 4chambers in GIF++ (both short and long tests performed)

Giada Mancini (LNF INFN)

If NA: hospital facility for refurbishment of all modules type at CERN!

- HV stability issue
- Resistivity issue -> Passivation
- New HV scheme

- Jan 2018: issues of HV Stability with first production MM NSW Quadruplets: Several HV sectors showing high currents and in some cases were prone to discharging
- Restarted a **limited R&D Program** addressing:
 - Maximum sustainable voltage without high currents nor frequent discharges
 - Critically revisit possible design issues (identification of weak points) in both Drift and RO panels
 - Mesh type (grid sizes selected mesh demonstrated not to be optimal, mesh calendering)
 - RO boards and panel cleaning
 - Effect of humidity inside the panels
 - Long term stability HV tests

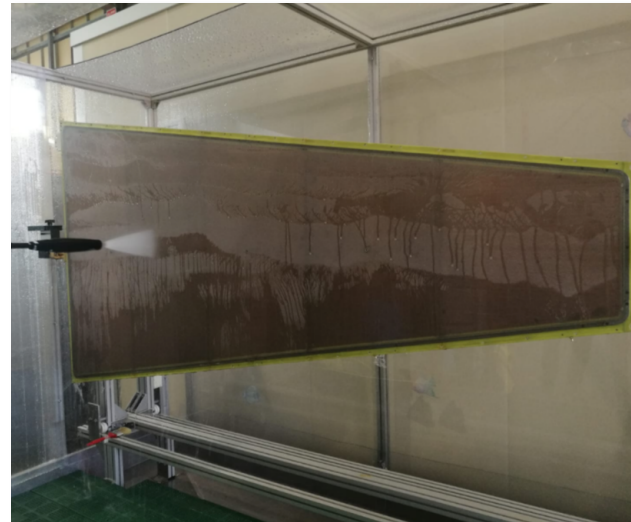


Main issues identified to be:

- **residual ionic contamination** of boards and panels from industrial processing and handling => **improve the cleaning procedures**
- Possible effects from **mesh mechanical imperfections** => **implement mesh polishing**
- Clear **correlation of currents with humidity** (FR4 hygroscopic - board dimension affected by humidity: $\sim 400 \text{ mm/m}$ from 0 to 50% RH) => **increase gas flow rate and monitor humidity**

Micropolishing cleaning procedure:

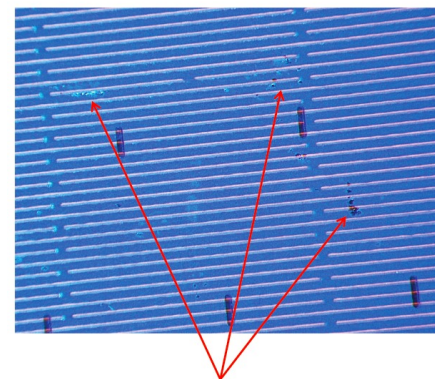
- Hard and soft brushes to distribute detergents
- Accurate washing with hot and demineralized water
- Drying in a box with a ventilation system at $\sim 40^\circ$



Main purpose of wet cleaning (and scrubbing):

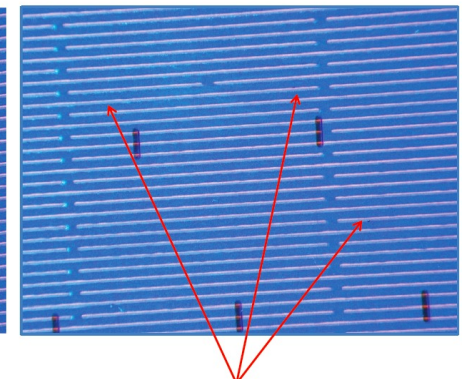
- **remove remnants from the PCB production:** dirt and solid deposits from the RO boards -> **mostly responsible of "ionic component"**
- remove dirt from the mesh (and trapped wires/chips)

Before cleaning



Production remnants

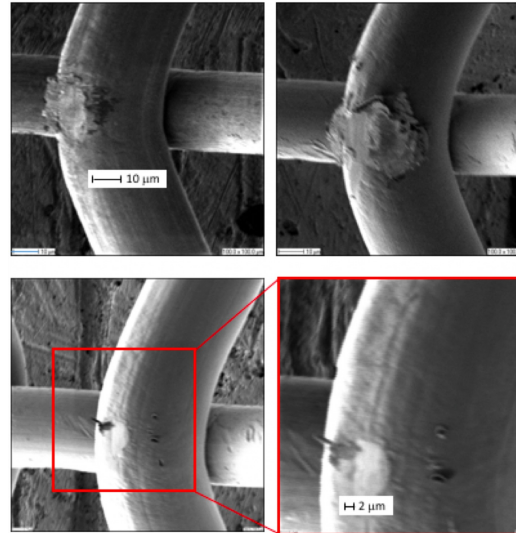
After cleaning



Production remnants removed

The mesh grids used for the ATLAS MM are not flattened by calendaring and may present some imperfections, which can produce discharge if pointing toward the resistive strips

-> **polishing with a very fine sandpaper to remove or smooth these imperfections**



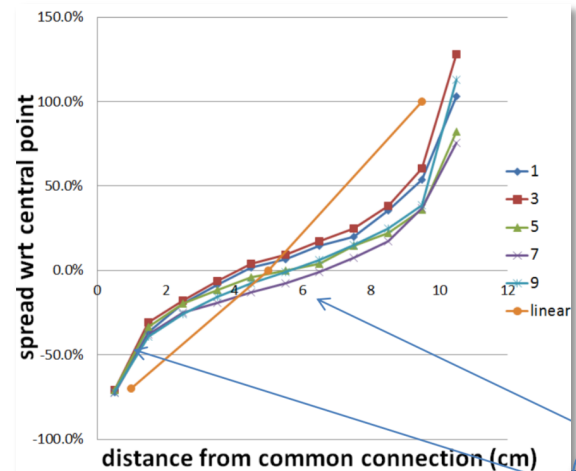
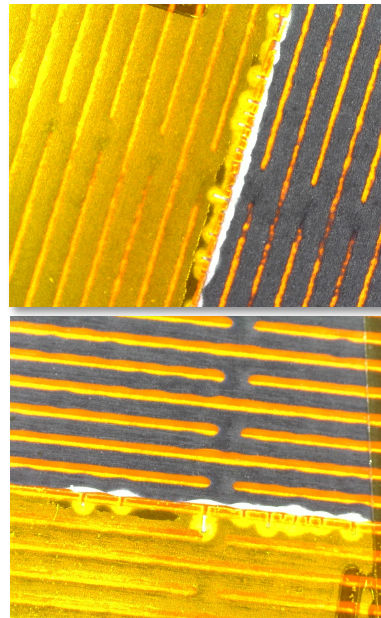
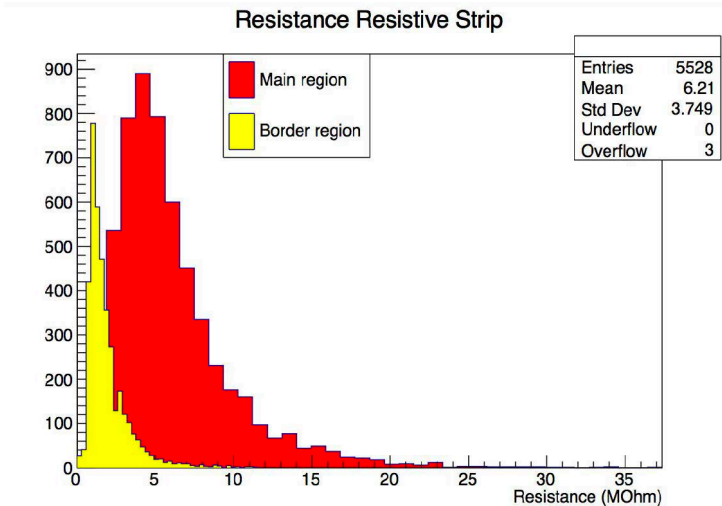
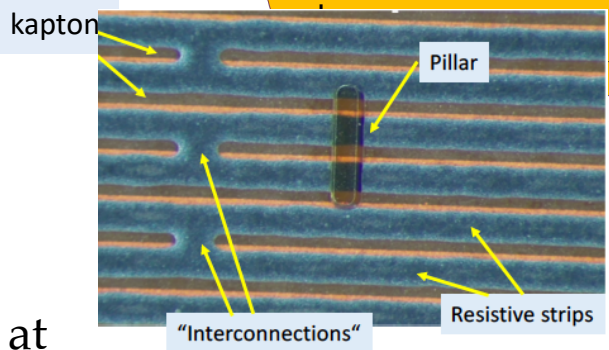
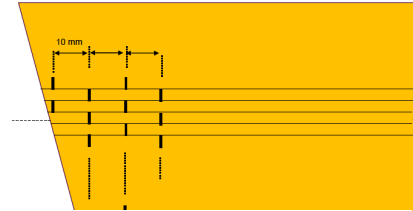
The described cleaning procedure, together with the mesh polishing has been adopted at all sites and large improvements have been observed in HV stability behavior.

-> Production resumed BUT still in all chambers few HV sectors have problems so that further investigations went ongoing in parallel with the production.

The resistive strips of the ATLAS MM are ink-printed on a kapton support

The resistive strip layout presents interconnections with a defined pattern -> to have more uniform resistivity in the board

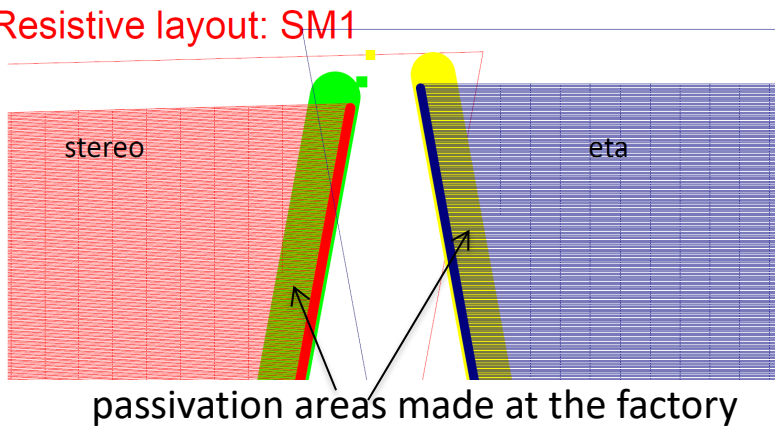
Analysis of **discharges** showed that in many cases they are **localized on resistive strips junctions crossing the piralux rim, the edge of the active area** (1cm wide zone passivated at the factory)



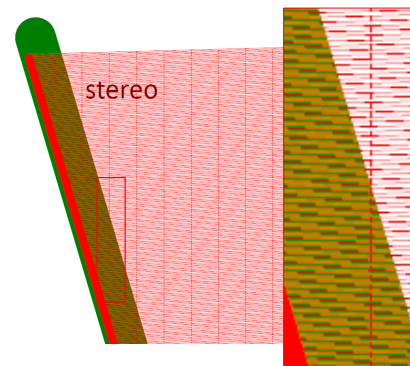
50%

- The resistive strips layout is not the same for all PCB types (some PCB types were more affected than others by discharges)
 - For example LM1 both stereo and eta, SM1 stereo but not eta panels

Resistive layout: SM1

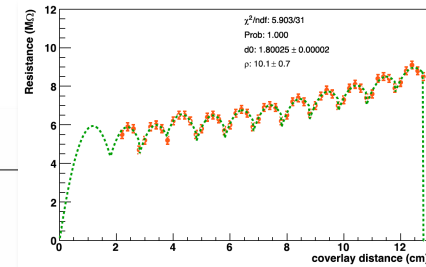
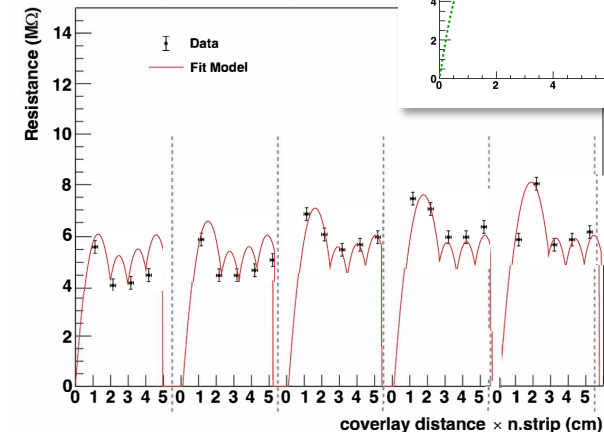


Resistive layout: LM1



- Resistance locally can be significantly lower than what obtained with 1cm² probe
- Strong dependence on the layout
- Local defects can be undetected
- Local resistance behavior can be predicted via simulation

Fit Resistance over 5 strips



Passivation:

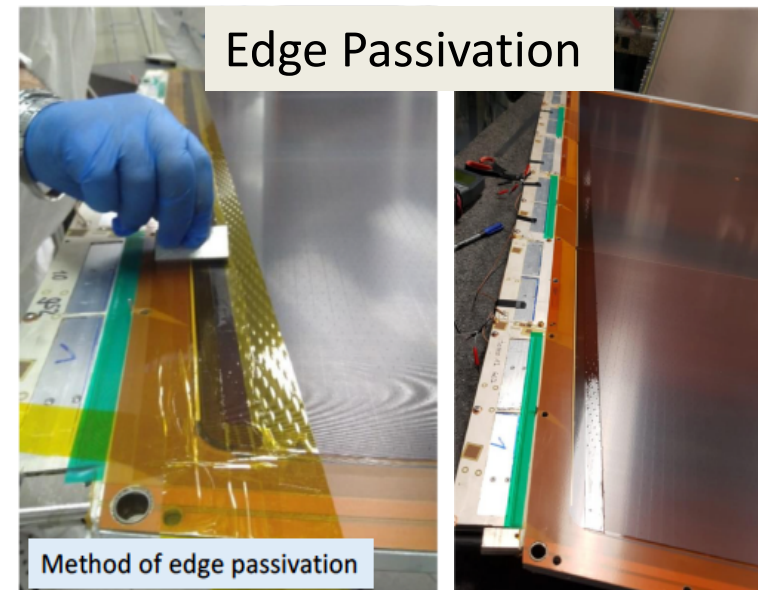
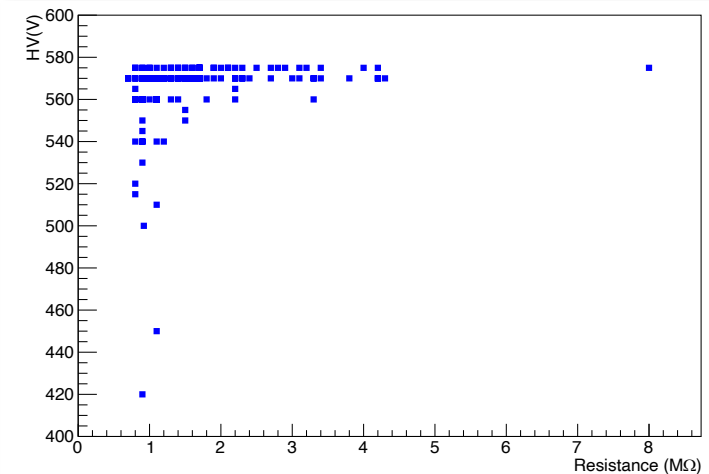
Resistance measured with megger and a 1cm^2 probe, at different distances from the pyralux rim applied by the PCB factory, w.r.t. the silver line

The minimum resistance (R_{\min}) measured near the edge of the active area is sometimes very low ($<0.4\text{ M}\Omega$)

Clear correlation between bad sectors and R_{\min} !

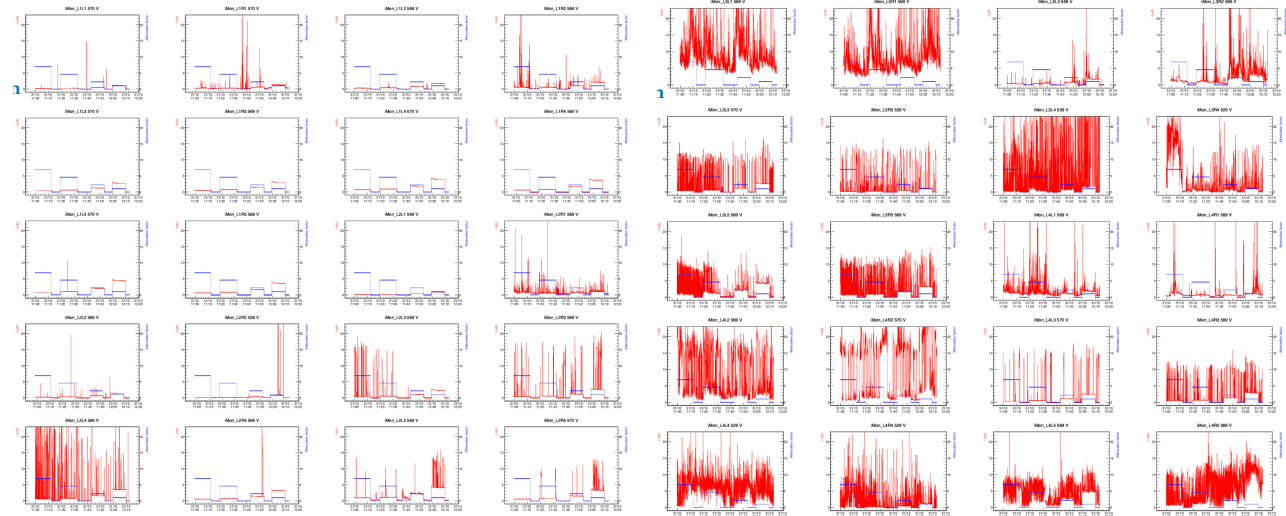
Edge passivation established to mitigate this problem (initially for the SM1 stereo panels, then extended to all construction sites)-> passivation of a region along the sides of the PCB through deposit of a thin layer of araldite, wide enough that the first active area has a $R_{\min} >1\text{ M}\Omega$

The solution is not optimal, because we give up active area (lowering the geometrical acceptance of the detector) which in some cases is rather large



LM1 chambers under gamma irradiation at GIF++

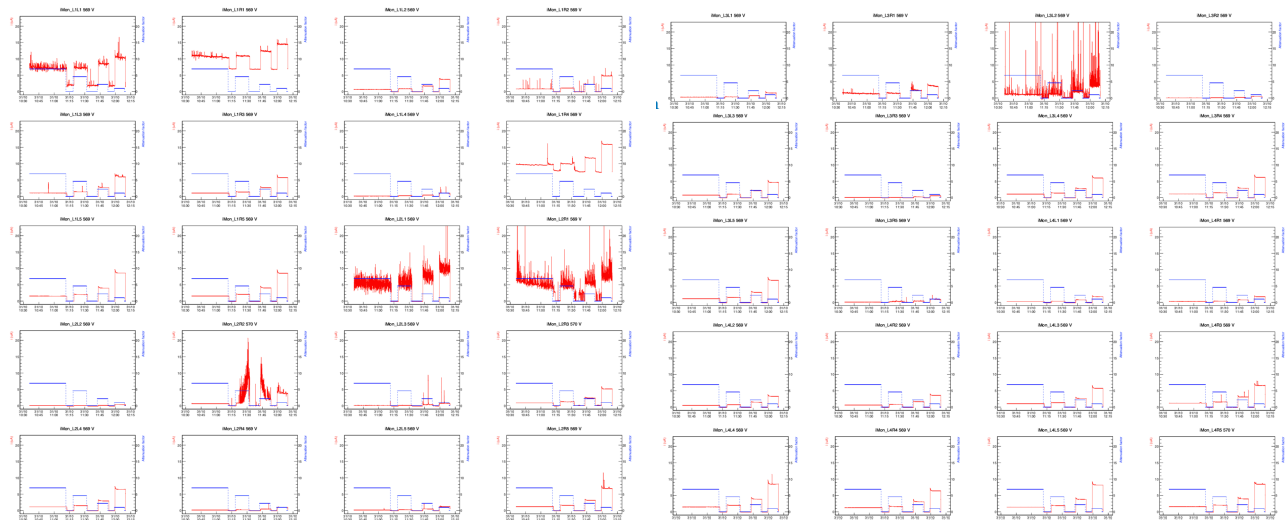
LM1-M8
not passivated
24 HV sectors not
passed
requirements



Lorenzo Pezzotti - November 2019 Muon Week

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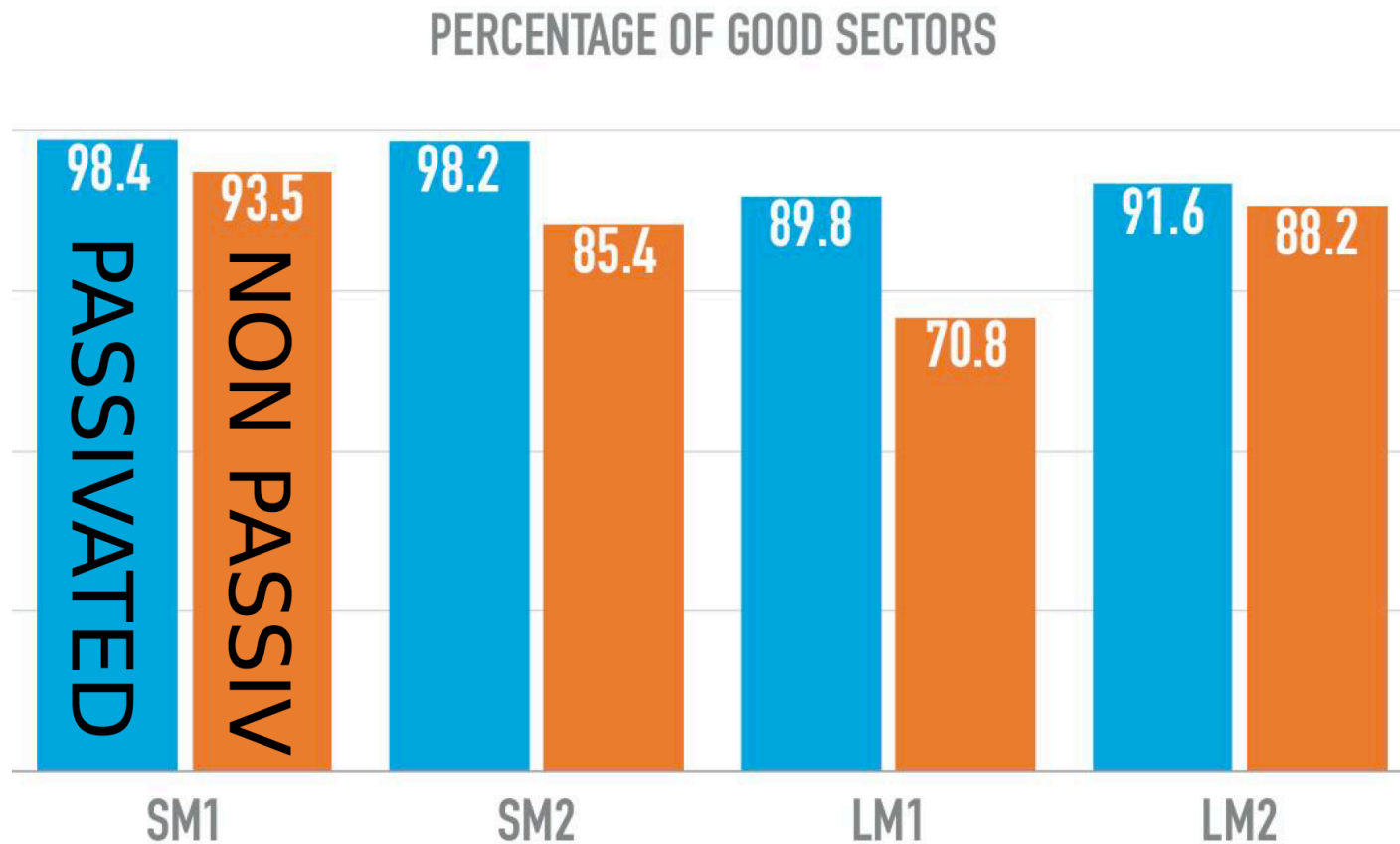
LM1-M5
passivated
6 HV sectors not
passed
requirements



Lorenzo Pezzotti - November 2019 Muon Week

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Effects of the passivation are confirmed by the percentage of good sectors (i.e. $HV \geq 560V$) for the chambers on the DW integrated so far



New splitter boxes needed to go from the layer granularity scheme to the so called half granularity scheme:

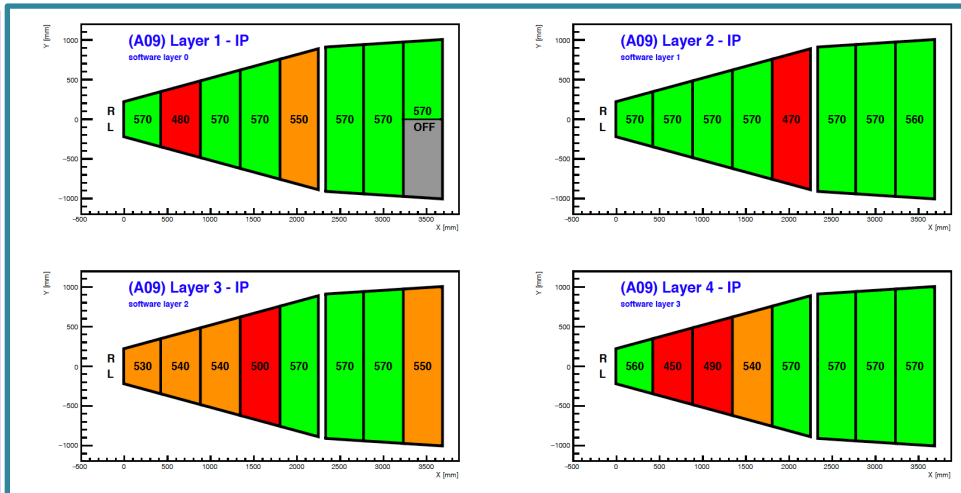
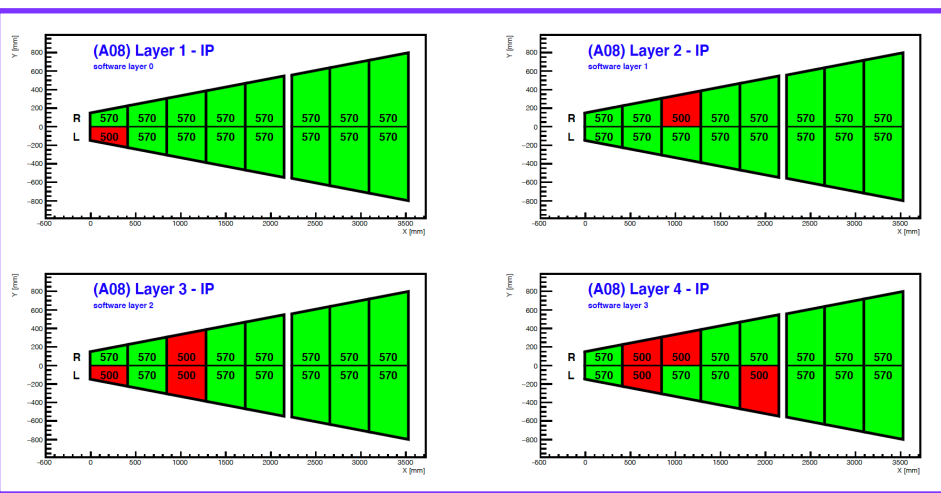
OLD: 1 HV channel per chamber layer + only 1 HOL available per chamber (20 HV channels per DW): weak channels either off either at the lower HV value for each chamber

-> **NEW:** 1 pcb per HV ch, 2 adjacent HV sections (64 HV ch per DW)!



Old scheme

New scheme



Successfully tested! Possibility to remove jumpers to unplug bad HV sections.

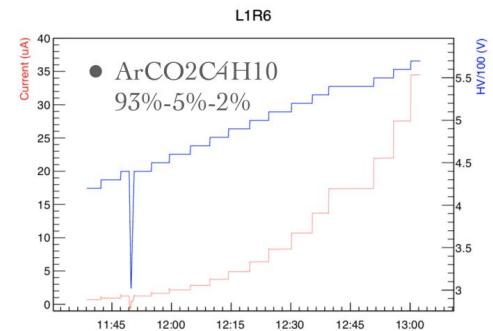
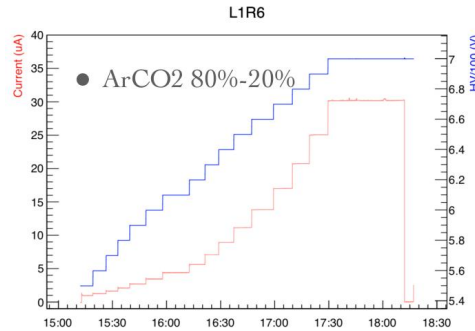
- Ongoing studies:
 - Test on different gas mixtures at GIF++ under gamma irradiation and at the DW Cosmic Stand in bb5
 - Test with pure Argon to recover resistive behaving sections
 - Test taking data with high current

Test on different gas mixtures, aiming to optimize the behavior under HV in terms of stability, current values, working point

- Gas mixtures under test:
- Ar:CO₂ = 93:7 (standard)
 - Ar:CO₂ = 80:20
 - Ar:CO₂:iC₄H₁₀ = 93:5:2

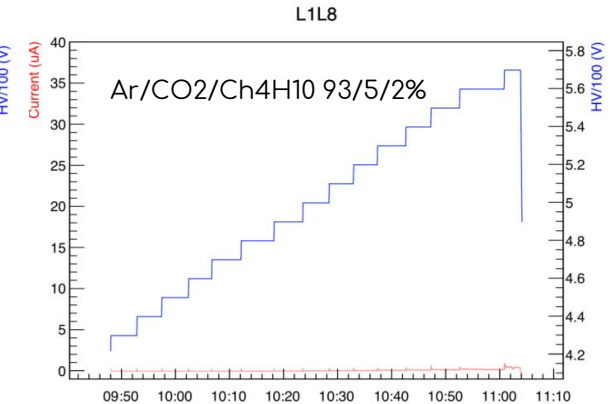
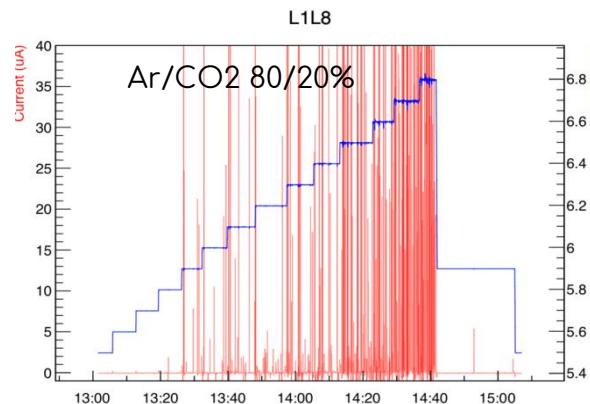
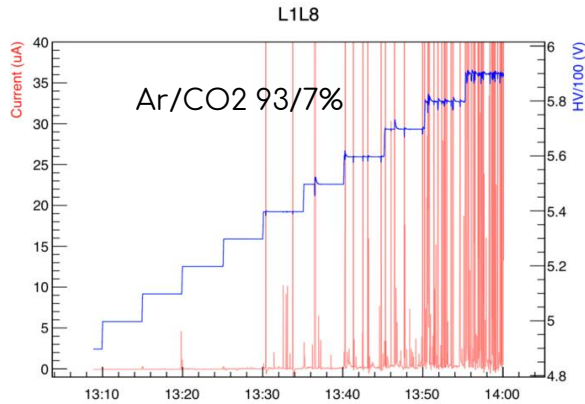
HV ramp up on good-behaving MM sectors:

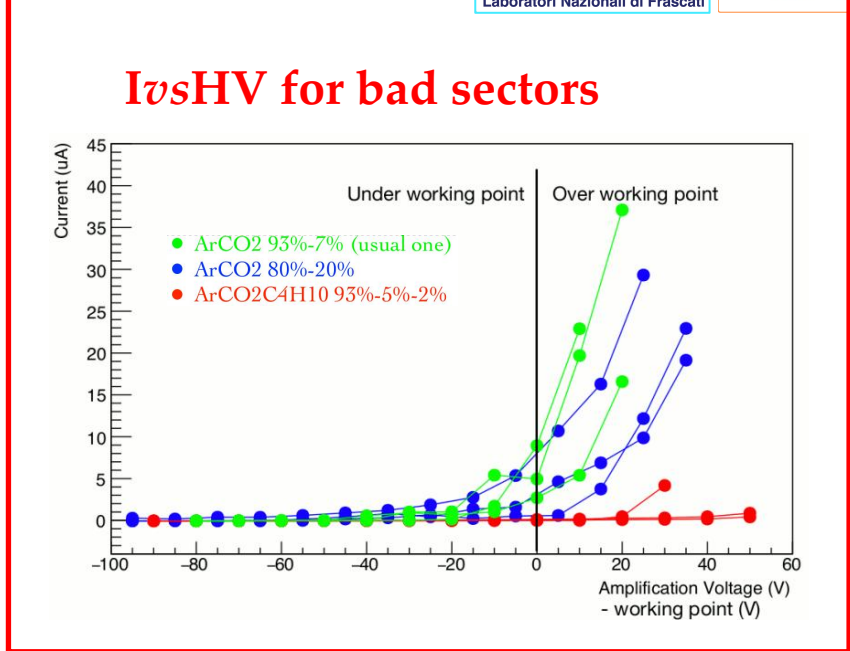
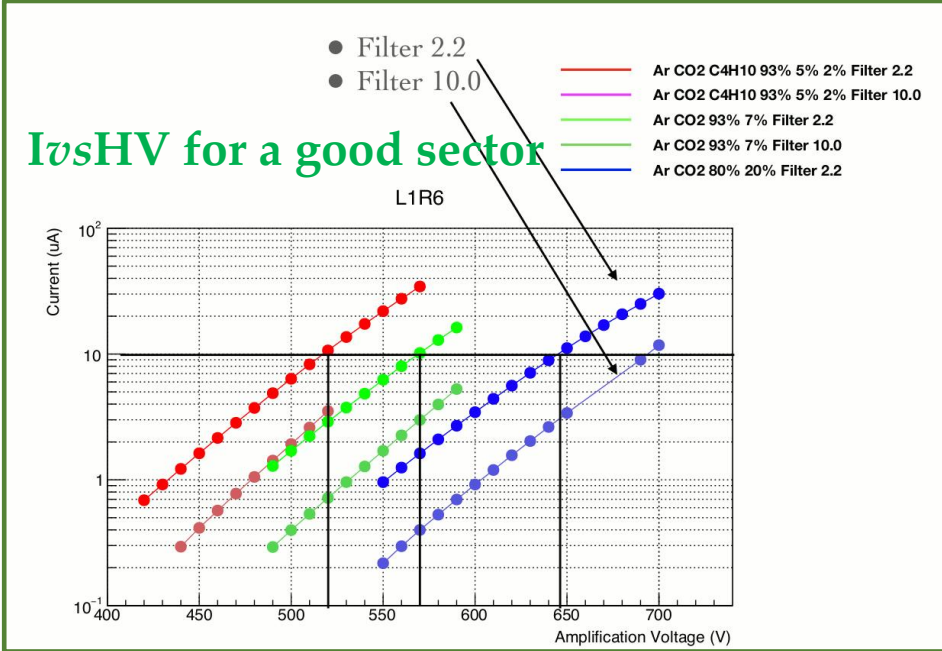
- smooth exponential ramp up of the current
- no spikes



HV ramp up on bad-behaving MM sectors, presently high spike rate:

- not much difference between the two binary mixtures
- **the addition of the small fraction of iC₄H₁₀ very effective on spikes suppression**





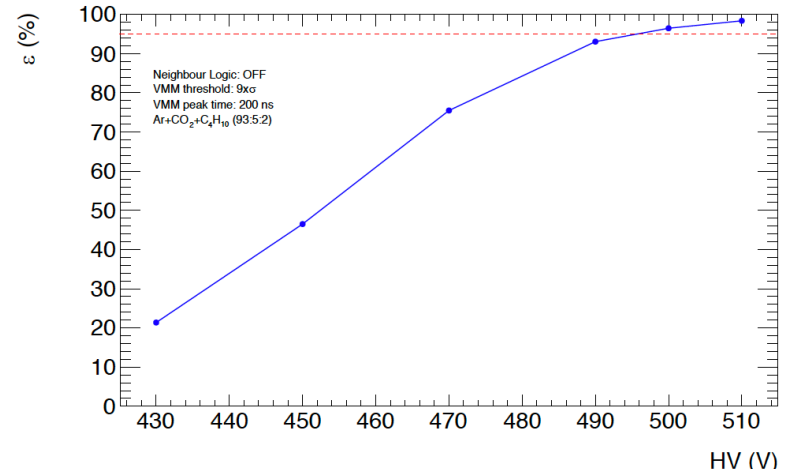
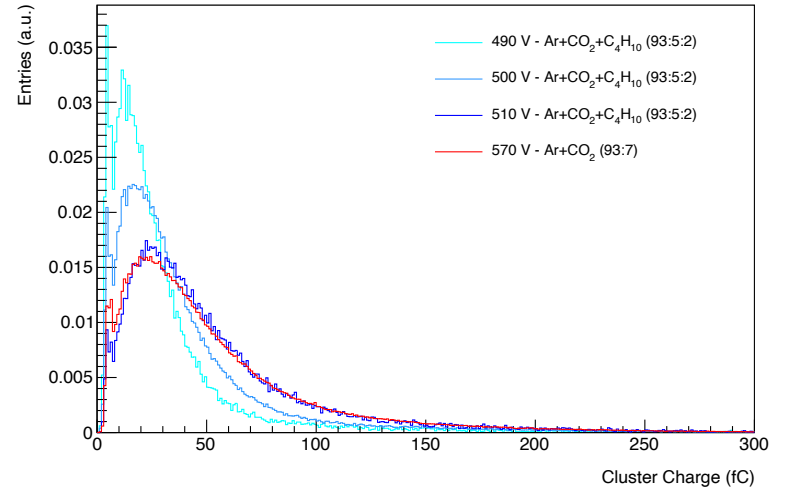
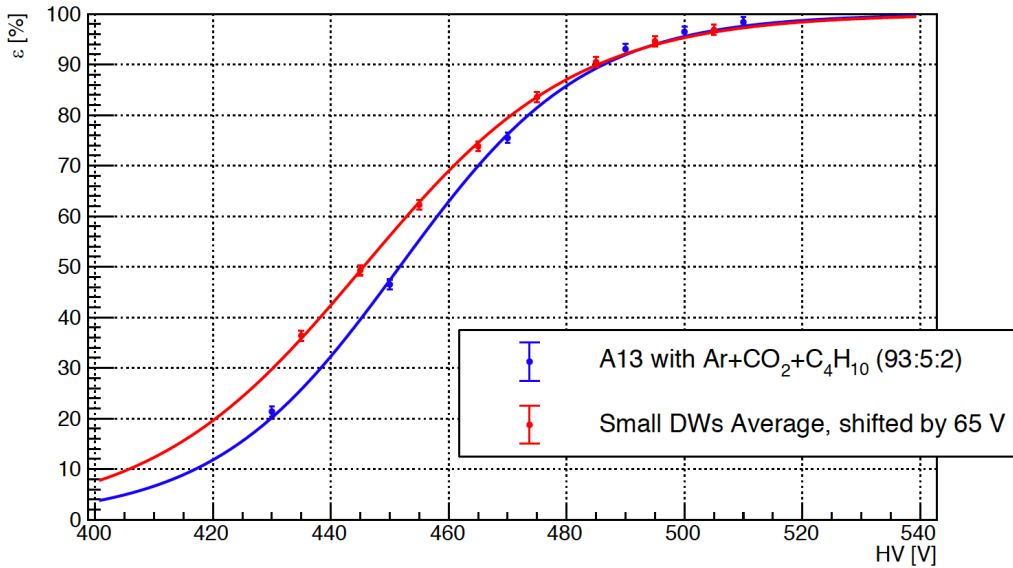
- **iC4H10 allows to run at significantly lower amplification voltages**
 - “Bad” HV-sectors behave better with the Isobutane enriched mixture
 - Mixture with 20% CO₂ also look slightly better than the standard mixture
- C4H10 seems to improve the sparking picture for NSW MMs
- > tends to **create deposit** (mainly for wire chambers)
 - > **MM and in general MPDGs are known to behave better in term of ageing**

Results have been confirmed by several tests at construction sites and by tests on Large DW at the DW Cosmic Station in bb5:

Isobutane allows to lower the working HV point while keeping:

- Same efficiency @ 495 V
- Same cluster charge @ 507 V
- Same strip charge/uTPC @ 520V

MicroMegas efficiency

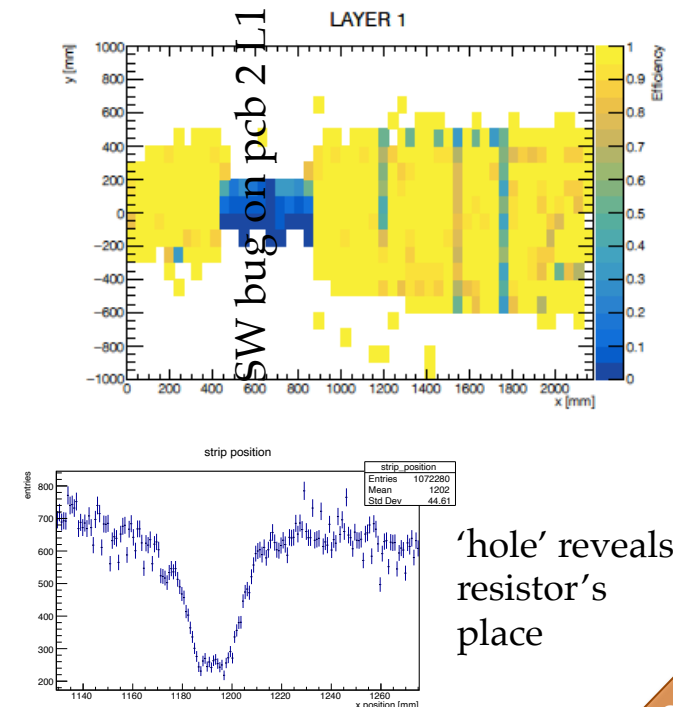


Long-term aging test on resistive MM performed with this gas mixture.

SM1 M31 has been tested at GIF++ under Iso enriched gas mixture for 4 months:

- L1L3 and L3L2 became resistive (L1L3 6.6 MΩ resistor -> successfully tried data taking in this demanding situation)
- L4L3 high current above 350V -> tested with pure Argon curing (Rui's recipe)

| SECTOR (LAYER PCB SIDE) | HV [V] | EFFICIENCY [%] | SECTOR (LAYER PCB SIDE) | HV [V] | EFFICIENCY [%] |
|---|------------------|----------------|---|-------------------|----------------|
| L1 1 PIN (L) | 570 | 98.4 | L2 1 PIN (L) | 570 | 95.9 |
| L1 1 NO-PIN (R) | 570 | | L2 1 NO-PIN (R) | 570 | |
| L1 2 PIN (L) | 570 | 3.8 | L2 2 PIN (L) | 560 | 94.5 |
| L1 2 NO-PIN (R) | 0 | | L2 2 NO-PIN (R) | 570 | |
| L1 3 PIN (L) | 570 drawing 80uA | 97.0 | L2 3 PIN (L) | 570 | 98.8 |
| L1 3 NO-PIN (R) | 560 | | L2 3 NO-PIN (R) | 570 | |
| L1 4 PIN (L) | 570 | 96.3 | L2 4 PIN (L) | 570 | 97.9 |
| L1 4 NO-PIN (R) | 550 | | L2 4 NO-PIN (R) | 570 | |
| L1 5 PIN (L) | 570 | 91.9 | L2 5 PIN (L) | 570 | 96.6 |
| L1 5 NO-PIN (R) | 570 | | L2 5 NO-PIN (R) | 570 | |
| <hr/> | | | | | |
| L3 1 PIN (L) | 570 | 96.9 | L4 1 PIN (L) | 570 | 97.0 |
| L3 1 NO-PIN (R) | 570 | | L4 1 NO-PIN (R) | 570 | |
| L3 2 PIN (L) | 0 | 2.7 | L4 2 PIN (L) | 570 | 95.1 |
| L3 2 NO-PIN (R) | 570 | | L4 2 NO-PIN (R) | 570 | |
| L3 3 PIN (L) | 570 | 75.5 | L4 3 PIN (L) | 530 with Keithley | 78.9 |
| L3 3 NO-PIN (R) | 510 | | L4 3 NO-PIN (R) | 570 | |
| L3 4 PIN (L) | 570 | 92.6 | L4 4 PIN (L) | 570 | 96.8 |
| L3 4 NO-PIN (R) | 530 | | L4 4 NO-PIN (R) | 570 | |
| L3 5 PIN (L) | 570 | 97.0 | L4 5 PIN (L) | 570 | 90.4 |
| L3 5 NO-PIN (R) | 570 | | L4 5 NO-PIN (R) | 550 | |
| <hr/> | | | | | |
| MODULE AREA AT 570 V: 75.7 % | | | MEAN EFFICIENCY = 84.7 % | | |
| TOTAL MODULE BAD SECTORS (HV < 550 V): 5 (12.5 %) | | | MEAN EFFICIENCY WITHOUT BAD PCBs (3) = 94.8 % | | |



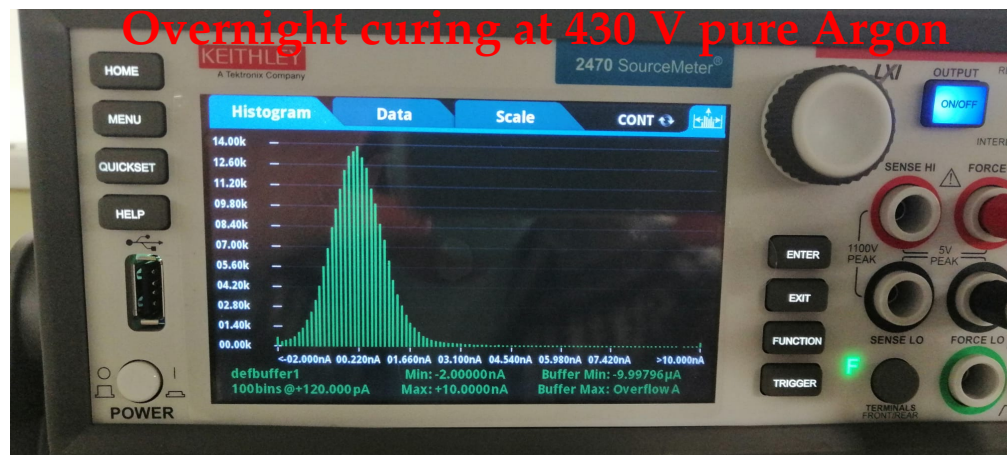
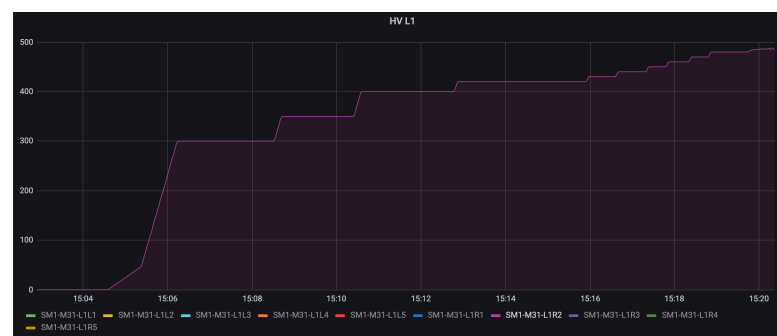
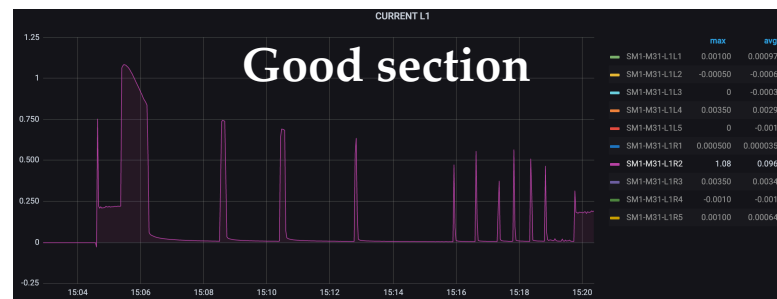
Recovery procedure tried in pure Argon for M31 with Rui.

One highly problematic channel (L4L3) have been powered with the Keithley power supply up to 460 V in pure Argon.

The idea: try to use Argon to clean the region by means of sparks -> need to stay in the working region

We used a very good sector to define the break down HV in pure Argon: 480 V
Then the aim was to try to go slowly up to that value using Keithley for the bad behaving sector:

- First day up to 430V (easy up to 400V, then by steps of 5 V), left for the night, then next day up to 460V
- only 24 h
- need longer time to go further



Pure Argon curing

L4L3 With Keythley at 530 V in ArCO₂



L4L3 at 490 V in Iso



- M31 has been reopened at the hospital facility at CERN
- Visual inspection on this particular section has not shown signs of problems in the active area
- Not conclusive but promising

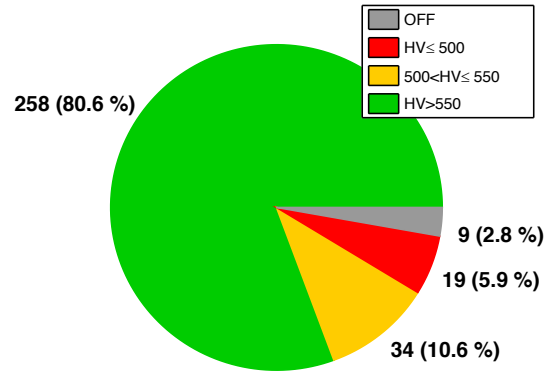
- NSW status up to now

Production wise:

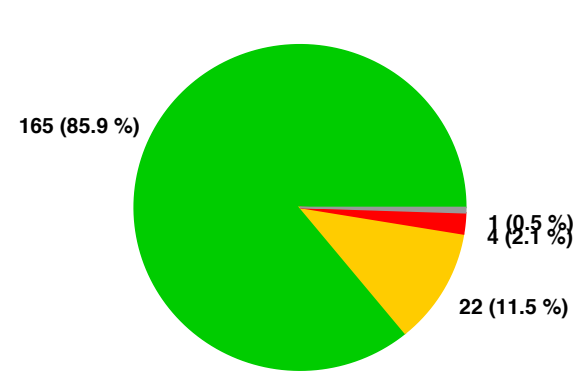
- SM1 finished
- SM2 finished
- LM1 7 chambers to go
- LM2 6 chambers to go
- 3 chambers to be refurbished at CERN

**HV statistics per pcb
(half granularity
scheme) on all the
DW validated and
accepted so far;
i.e. 1 to go for the
NSW A!**

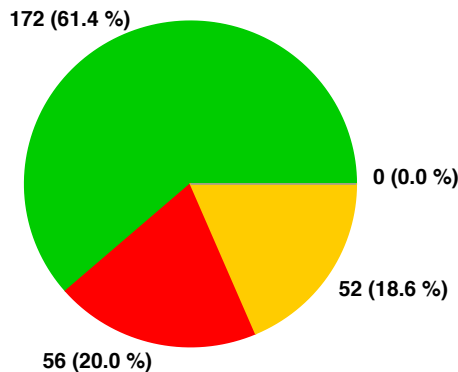
SM1 modules



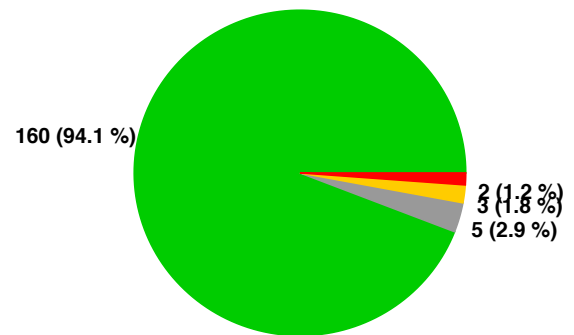
SM2 modules



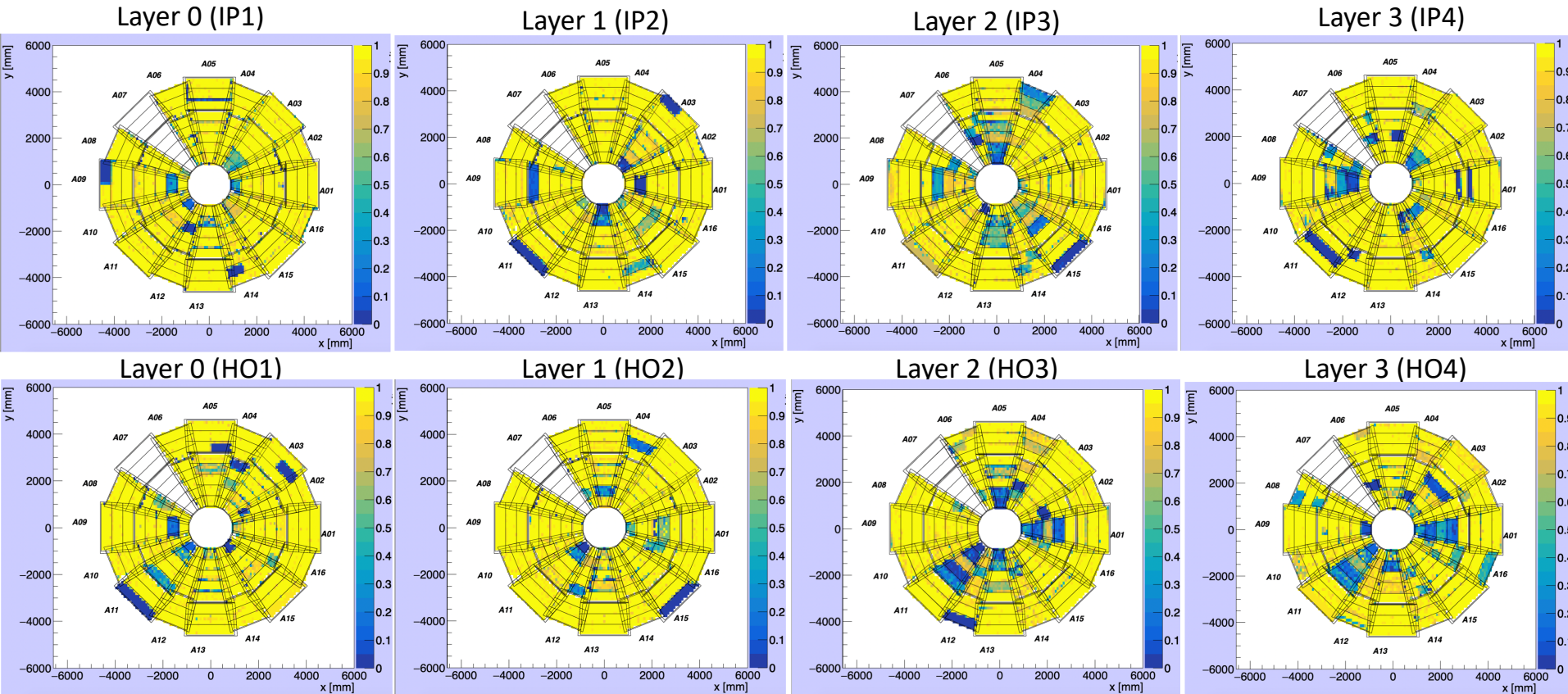
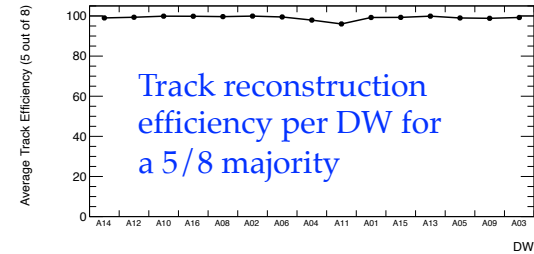
LM1 modules



LM2 modules



Display on the wheel of the measured efficiency for each layer of the NSW A measured with cosmics at the DW CRS in bb5



- Micromegas have been chosen for **their great performances in tracking particles up to high fluxes** in view of the increasing luminosity of LHC
- The **construction of such large area detectors presented many challenges** which have required further studies to be addressed
- The combination of the **low resistivity of the produced resistive foils** and a non-optimal layout of the resistive-strip interconnection path, produced regions in the proximity of the silver line unprotected against discharges
 - **The introduction of the passivation procedure allowed to cure the majority of HV issues but with the cost of loosing some active area** (particularly important for the smaller PCB at large eta)
- **Studies with Isobutane enriched gas mixture show promising results in terms of improving the HV stability of the chambers** -> long term tests ongoing
- **Test of possible curing with pure Argon** started -> promising to recover sectors!

NSWA ->
DWs ready to go
on the wheel!

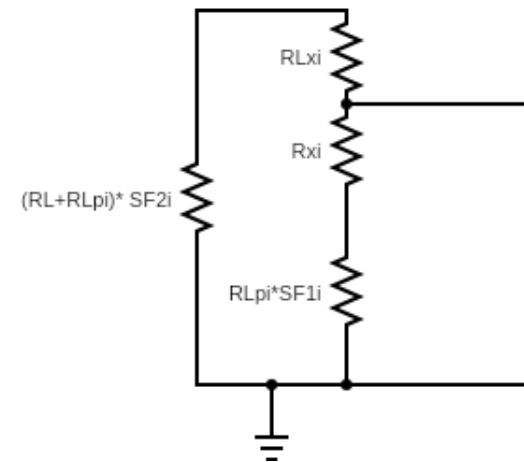
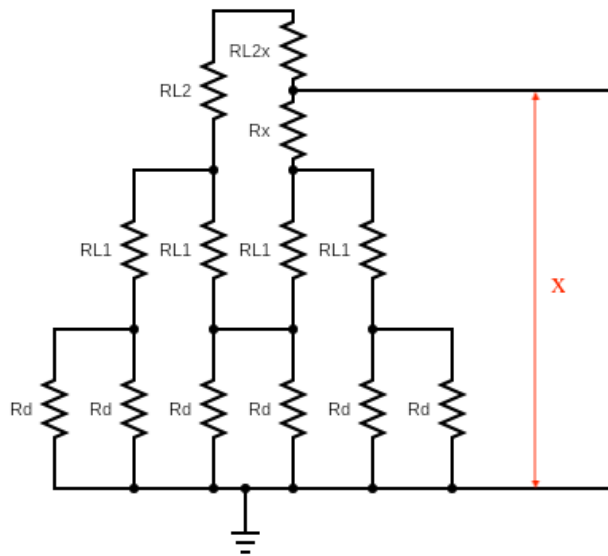


Thanks for your attention

Backup

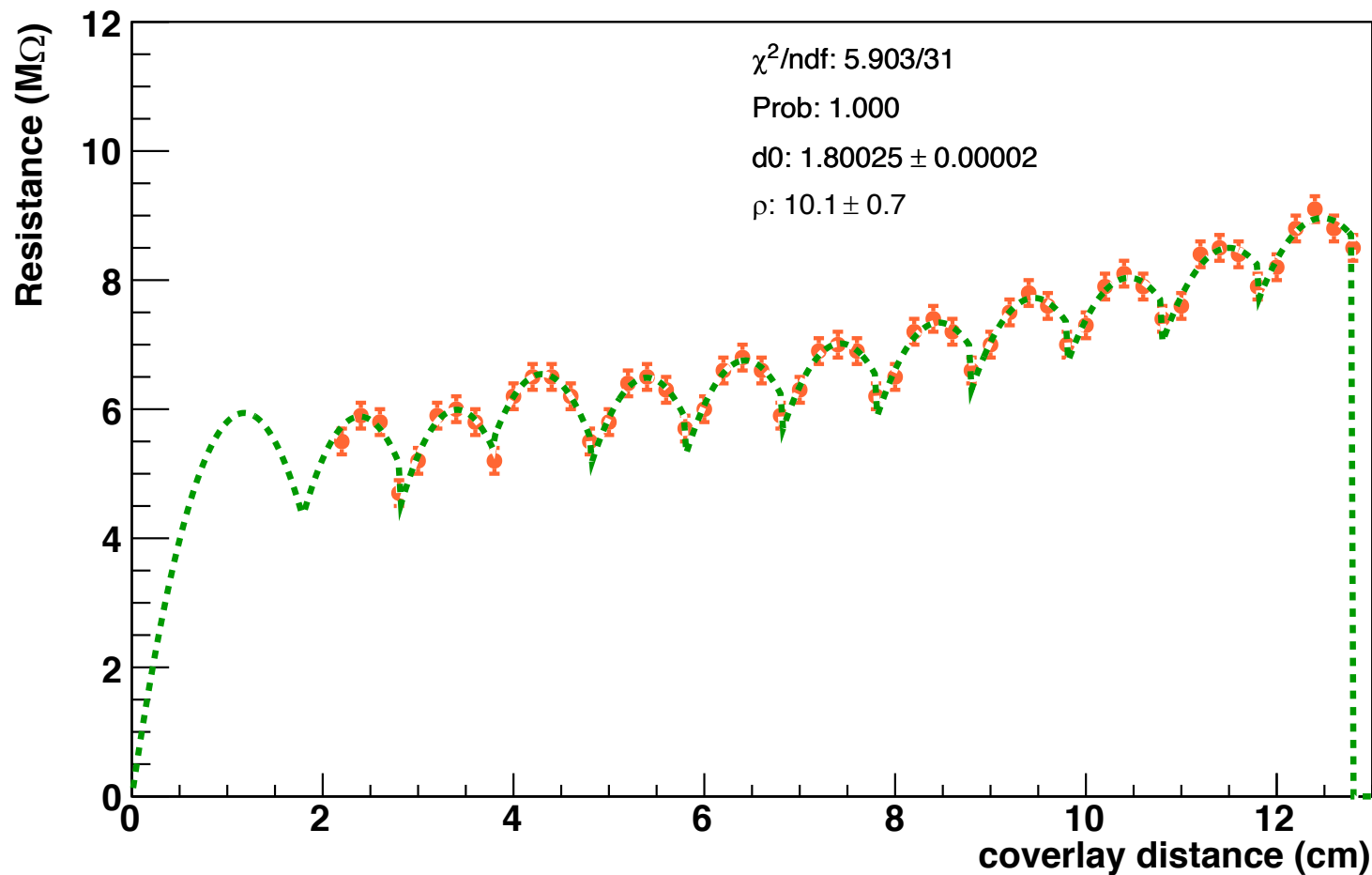
Build a model of the resistive PCB circuit to see the behavior of the resistance as function of the PCB layout

- Start from a simplified circuit scheme (on the right)
- 1D model of one strip as a step function based on the interconnection step i :
 - remap R of each ladder step in effective resistances which take into account the contributions of other parallels in the circuit which has been neglected introducing Scale Factors (SF) \rightarrow Recursive model



$$R_{strip,i} = (R_{xi} + R_{Lpi} \cdot SF1_i) \parallel (R_{Lxi} + R_{Lpi} \cdot SF2_i)$$

- Cosenza electrical resistance measurements on one strip (2 mm sample)
→ 1D model fit data up to twelfth interconnection



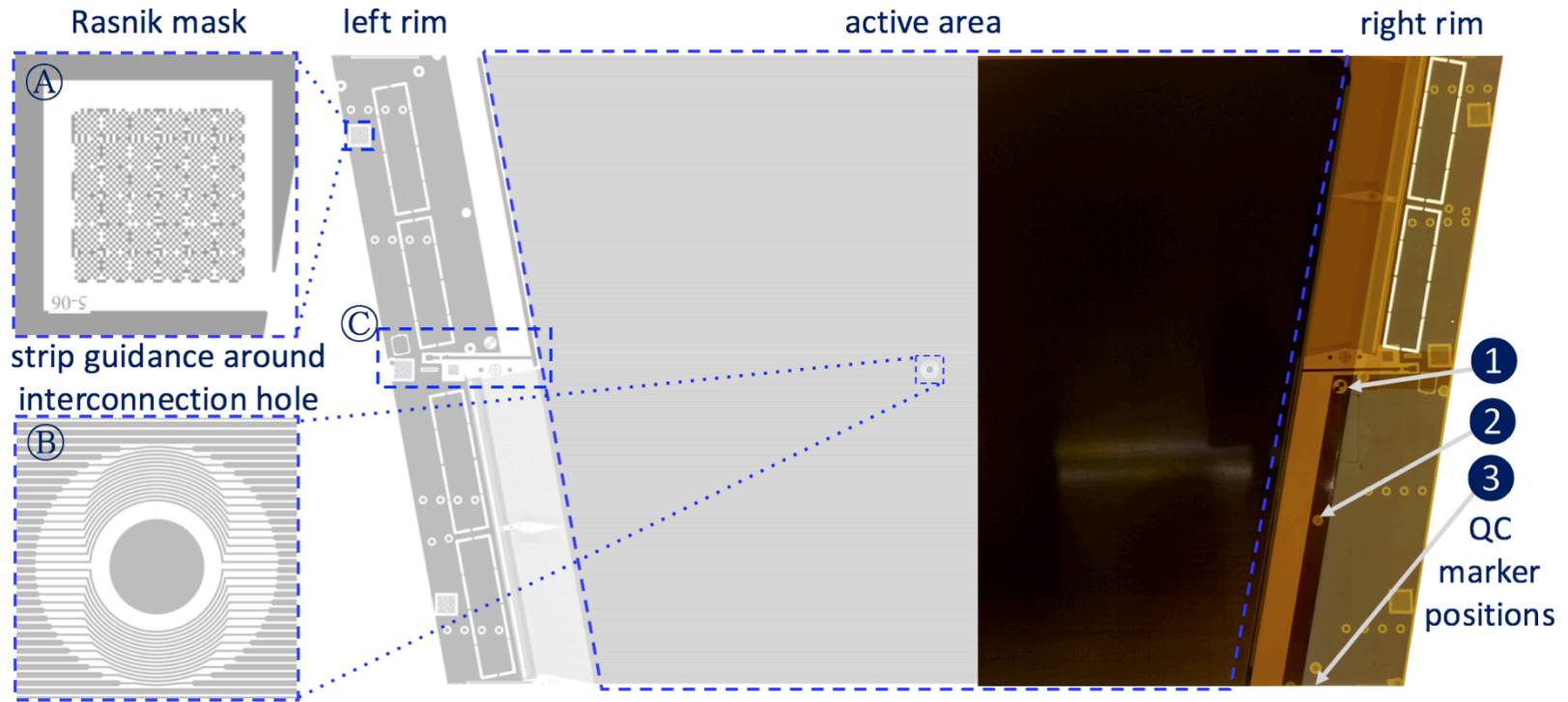


Figure 3. Drawing of a Micromegas anode PCB copper pattern (left) and picture of the finalized board (right). The location and structure of Rasnik masks (A), strip routing around holes (B) and the center of the rim area (C) (see figure 4) are shown, as well as the location of three quality control markers (see figures 5, 6 and 7).

Dry cleaning and HV tests:

- Remove dust
- Clean with dedicated roller the surface of PCBs and Mesh using also a nitrogen gun
- check HV tests using the MeshTool
 - > HV test in air and gas leak test performed gap by gap
- Insert the 10 Pins 2mm diameter to align the Front End electronic boards

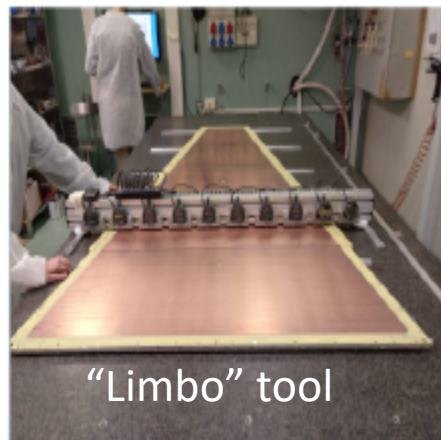
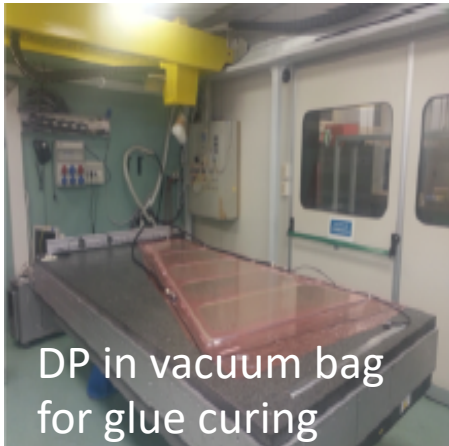


Panels need to be aligned one with respect to the other by alignment pins:

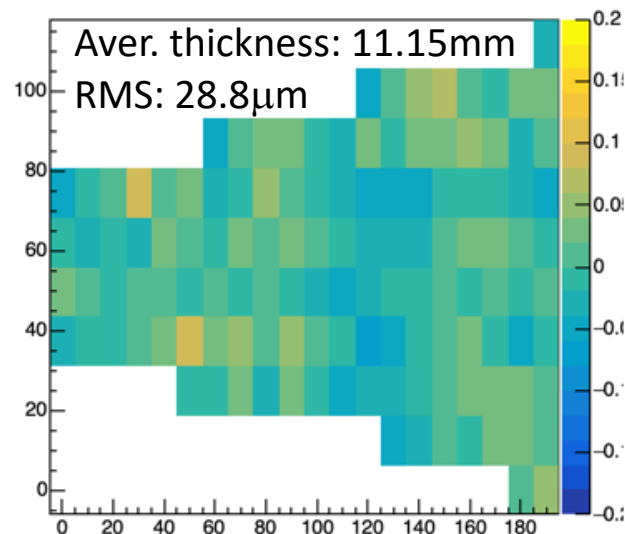
- Load Cells used on both sides of the panel
- Weight of panel loaded on alignment pins displayed on screen
- Micrometric screws turned slowly to reduce it as much as possible ($< 200\text{-}300\text{ gr}$)
- Then the panel is pushed towards the assembly structure



Drift panels construction



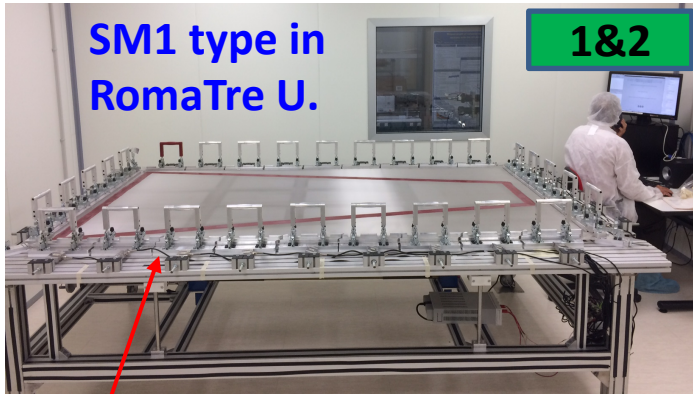
- Drift Panels for **SM1** assembled with the **vacuum bag technique** in Rome
- Dimensions of the components (PCB, frames, honeycomb) checked before use. The height is measured with a *linear height* or the *limbo tool*. In both cases the precision is of few microns.
- After panel assembly a HV of 1kV is applied between cathode and GND to check the electrical insulation.
- The planarity (RMS) and the thickness are measured using the *limbo tool*.
- Requirements (RMS < 37 μ m)



- **Panels in all other production sites** (both Drift and Readout) **assembled by using a stiff-back panel** (or a mixed technique), obtaining similar quality about planarity

Mesh Stretching

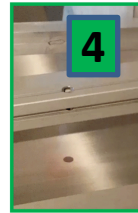
1. Mesh clamping and stretching (to ~ 10 N/cm) with a custom made stretching device
2. Mesh gluing on trapezoidal transfer frame
3. Clamp release after glue curing and mesh cutting around frame
4. Perforations for interconnection holes
5. Washing and polishing with fine sandpaper
6. Gluing on bare drift panels



SM1 type in RomaTre U.

1&2

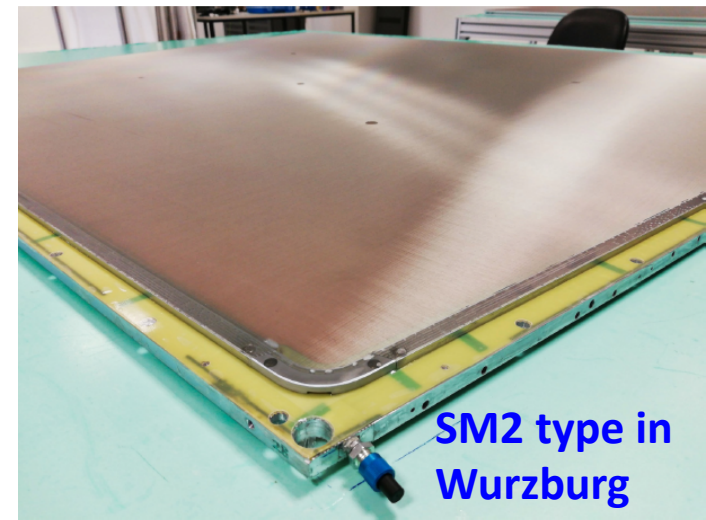
Mesh perforation



4

Mesh transferred on drift panel

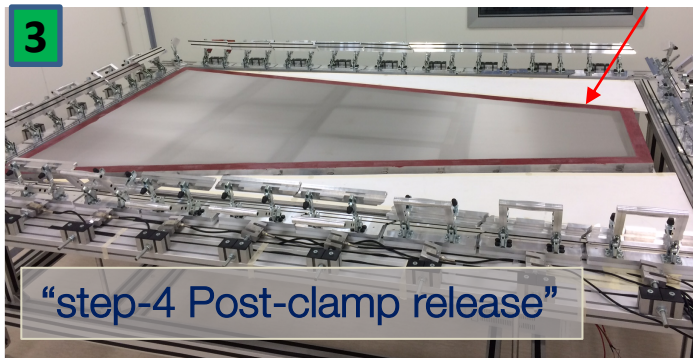
The final Drift Panel



SM2 type in Wurzburg

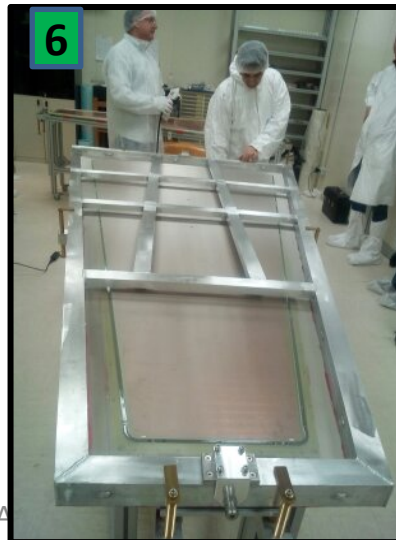
Load cell-connected clamp (28)

Trapezoidal frame



3

“step-4 Post-clamp release”



6

RD51 meeting

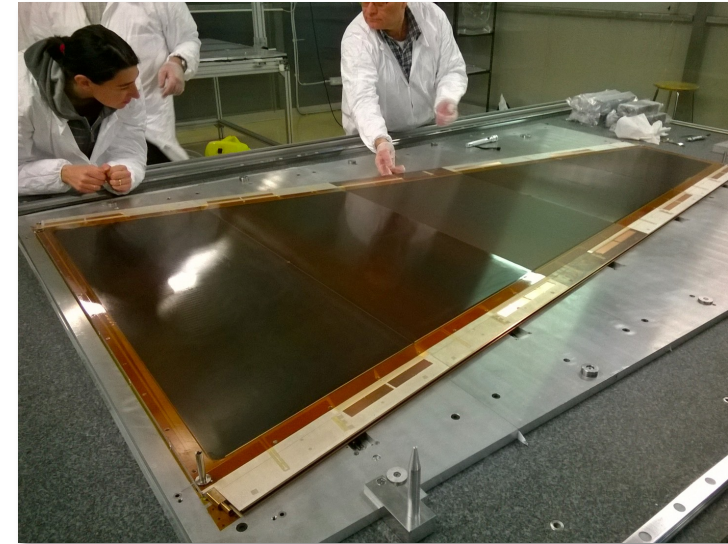
abio A

update

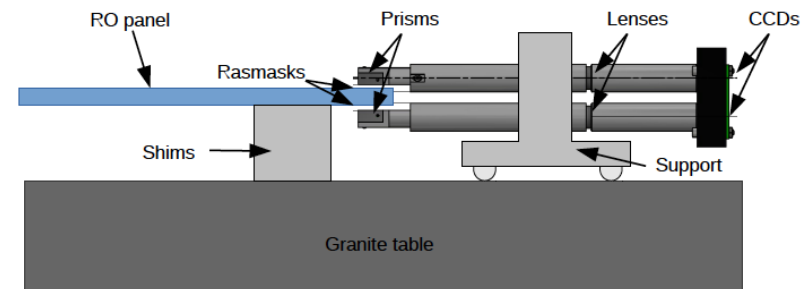
ReadOut panels construction

- All RO panels are built by using the stiff-back method (first layer on the granite table, second layer on a separate stiff-back plane)
- Requirements on panels planarity fully satisfied in all production sites
- QA/QC on alignments between PCBs and between layers of paramount importance
 - absolute alignment of the strips $\Delta\eta < 40 \mu\text{m}$
 - relative alignment of the layers $\Delta\eta < 60 \mu\text{m}$
- Alignments between PCBs performed by using calibrated jig and Contact-CCD or gantry/optical CMM systems, depending on sites, during construction
- Alignment between up and down layers measured via a rasfork tool (RASNIKtechnique)

ReadOut panel on granite table in Pavia



Concept of Rasfork measurements





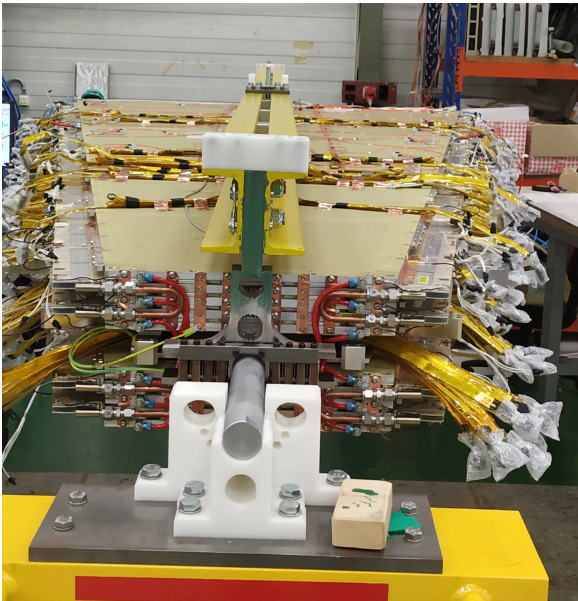
Installing gas distribution on the wedge support



Readout and Trigger cables installation

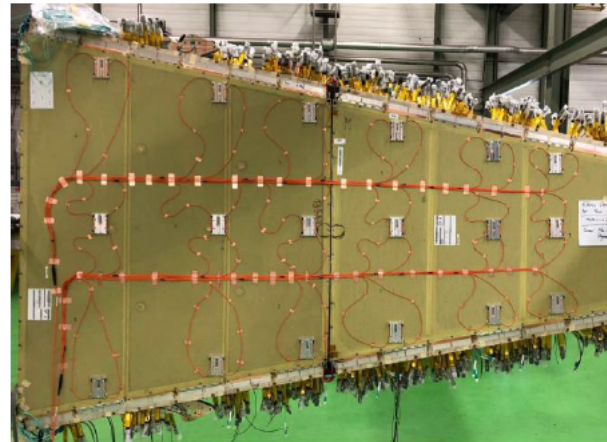


Placing of chamber on the wedge support



Both chambers on the wedge support

RD51 meeting



Routing of optical fibers for alignment

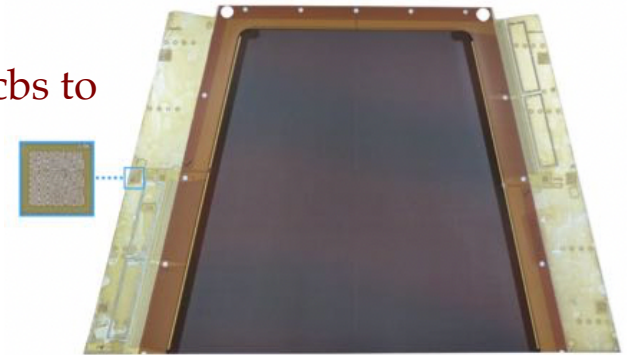
Fabio Anulli (INFN Rome) - ATLAS MM update



Installing Readout front-end cards

Alignment:

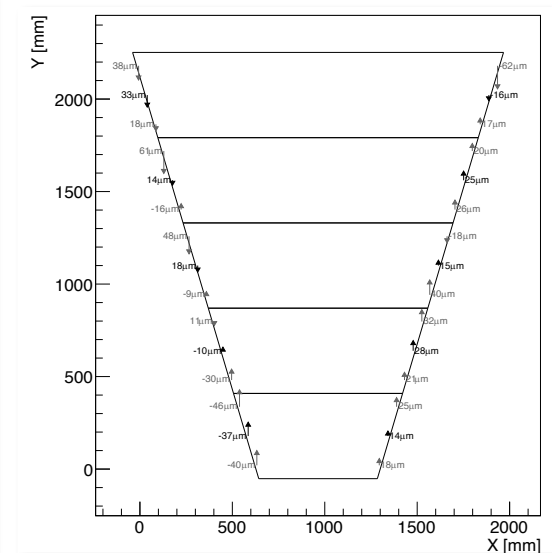
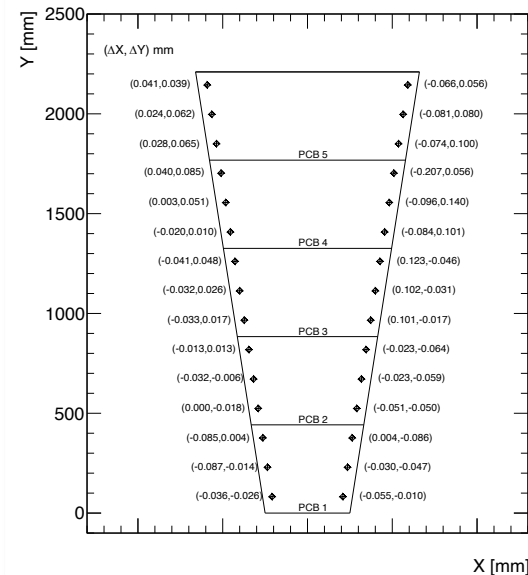
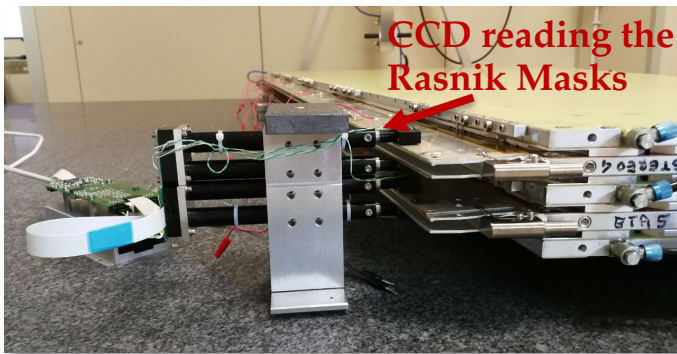
- mechanical supports to the PCB during panel construction
- coded masks read by contact-CCD on the external side of pcbs to ensure for the alignment and rotation of the strip:
 - absolute alignment of the strips $\Delta\eta < 40 \mu\text{m}$
 - relative alignment of the layers $\Delta\eta < 60 \mu\text{m}$



Rasnik technique:

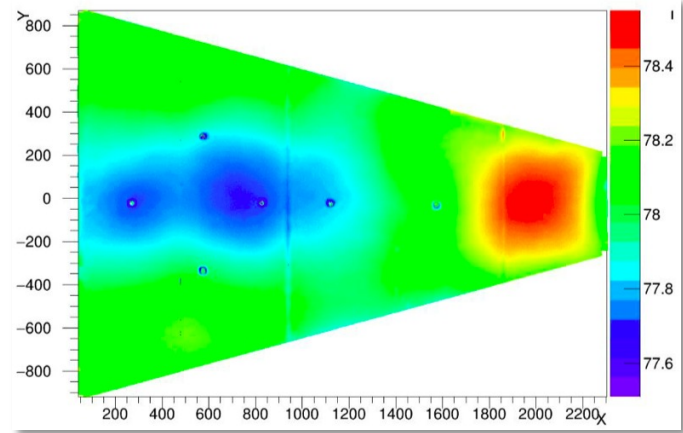
optical measurements of reference masks etched on the boards, aligned with the strips.

Return the relative alignments of boards side-to-side measuring position bias between top and down masks at $< 10 \mu\text{m}$

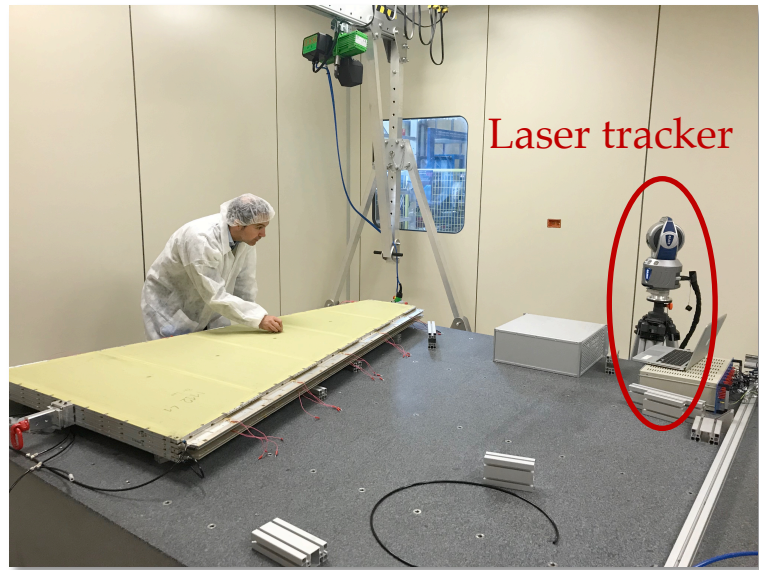
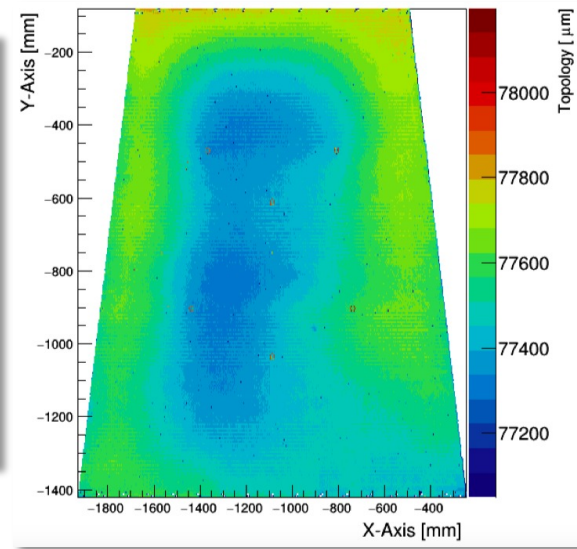


- Measurement of the **planarity** of the chambers surfaces via different methods
- Maps of the 2 surfaces
- Fit of the point-clouds
- Thickness: Δz between sides
- RMS $\sim 100 \mu\text{m}$

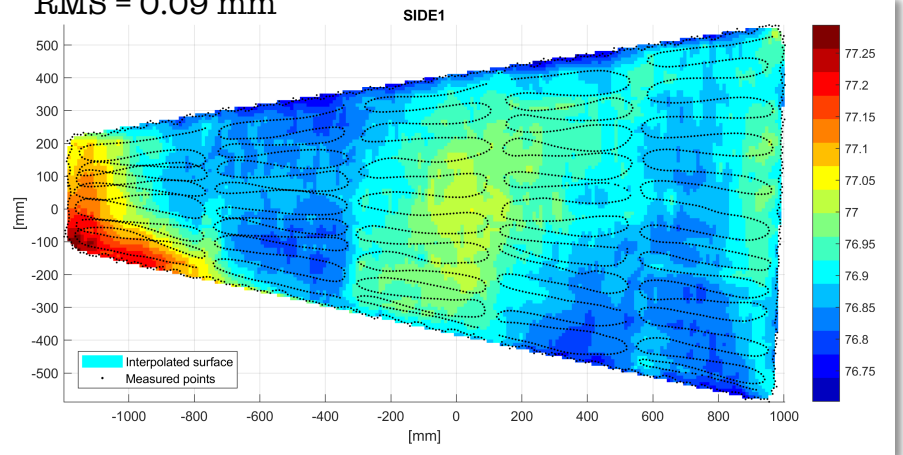
Thickness = 78.06 mm
RMS = 0.18 mm



Thickness = 77.51 mm
RMS = 0.11 mm

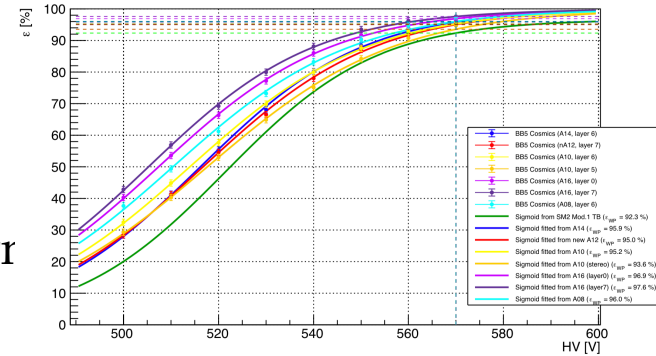


Thickness = 76.91 mm
RMS = 0.09 mm



HV nominal efficiency on NSWA integrated sectors

- Nominal Efficiency in Ar-CO₂ used to validate the chambers (from NSWA Small DW statistics)
- Same criteria to validate in HV the DWs (with the turn on curve taken with SM2 Mod0 during testbeam)

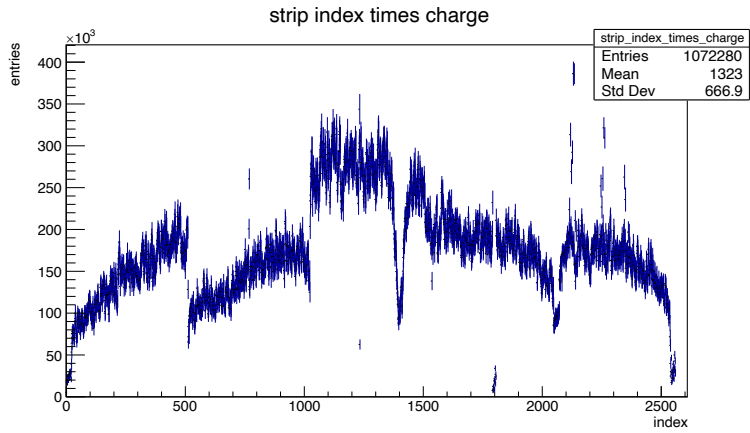
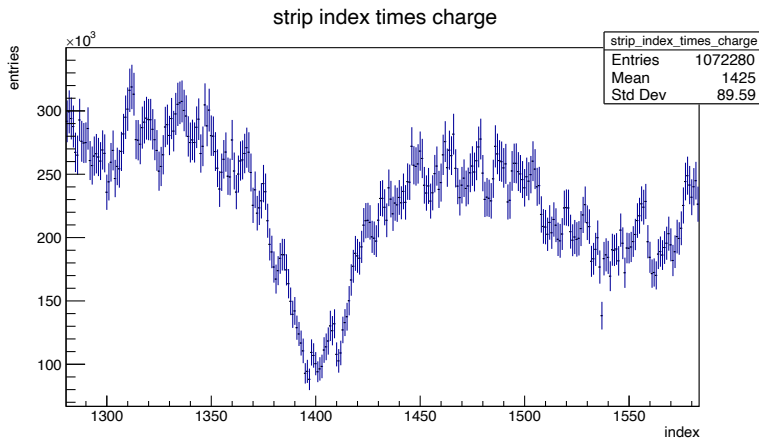
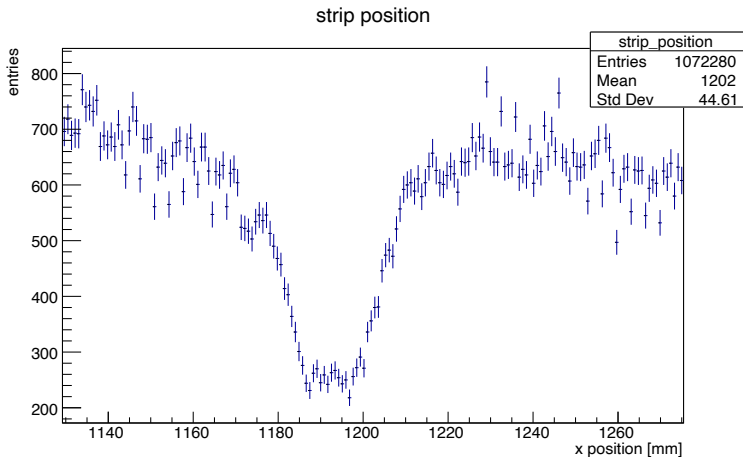


Summary of the HV Results of the Small DW validated so far:

| | Passivation | NE DW | | Passivation | NE DW |
|-------------|-------------|--------------|----------------------|-------------|--------------|
| A14 | 1 / 4 | 92.6% | A13* -> NA | No | 53.9% |
| A12 | Yes | 91.9% | A11* | 1 / 4 | 71.9% |
| A10 | Yes | 95.6% | A01* | Yes | 80.6% |
| A16 | 3 / 4 | 91.6% | A15* | 2 / 4 | 84.8% |
| A02 | Yes | 93.4% | A07* | Yes | 81.2% |
| A08 | Yes | 90.1% | A05* | Yes | 89.1% |
| A06 | Yes | 89.3% | A09* | 3 / 4 | 85.3% |
| A04* | 3 / 4 | 85.3% | A03* | Yes | 86.9% |

* Tested with the new splitter box

- A13 tested in Iso -> Whole DW working perfectly at 490 V, but 2 sections at 480 V
- A11 tested in Iso -> Whole DW working perfectly at 490 V, but 2 sections off and 1 at 350 V as from Ar-CO2 test



Clear 'hole' in correspondance to the short region:
blind analysis see later

| GAS time line | 20 Jul 2020 | 28 Aug 2020 | 7 Sept 2020 | 30 Sept 2020 | 16 Jan 2021 |
|---------------|------------------------------|---------------|----------------------------|--------------|----------------------------|
| SM1 M31 | in bunker Ar/CO ₂ | switch to ISO | back to Ar/CO ₂ | back to Iso | back to Ar/CO ₂ |

| | 14 Aug 20 (Ar/CO ₂) | 3 Sept 20 (Isob) | 1 Oct 20 (Isob) | 15 Nov 20 (Isob) | 17 Dec 20 (Isob) | 16 Jan 21 (Isob) | 18 Jan 21 (Ar/CO ₂) |
|------|---------------------------------|--------------------------------|--------------------------------|--|--------------------------------|-------------------------|---------------------------------|
| L1L3 | 570 V - 0.5 s/m | lost (resistive) 6% RH, 30 l/h | <= loss @30 mC | | | | confirmed loss |
| L2L2 | 565 V - 0 s/m | 490 V - 0 s/m | lost (resistive) 5% RH, 30 l/h | <= loss @30 mC | | | confirmed loss |
| L3L2 | 490 V - 0.24 s/m | 490 V - 0.2 s/m | 490 V - 0 s/m | lost std capacitive behaviour but unstable if HV>300 V 8% RH, 18 l/h | <= loss @1 mC | | confirmed loss |
| L2L5 | 570 - 0.95 s/m | 490 V - 0.4 s/m | 490 V - 4 s/m | strong spikes @ 490 V tripping, switched off and slow recovery started | 320 V slowly recovering | 500 V - 0 s/m recovered | confirmed recovery |
| L4L3 | 540 V - 1.2 s/m | 490 V - 0.4 s/m | 490 V - 0 s/m | 490 V - 7 s/m | lost (resistive) 7% RH, 18 l/h | <= loss @1 mC | confirmed loss |
| L1L5 | 570 V - 1 s/m | 490 V - 0.5 s/m | 490 V - 0.5 s/m | 515 V - 7 s/m | recovering | 520 V - 0 s/m | 550 V noisy |
| L3R4 | 570 V - 2.8 s/m | 490 V - 0.4 s/m | 490 V - 0 s/m | 475 V - 7 s/m | recovering | 490 V - 0 s/m | 520 V noisy |